VHF FM TRANSCEIVER

IC-H16 SERVICE MANUAL



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FOREWORD

Thank you for choosing the ICOM IC-H16, one of the most advanced VHF portables on the Land Mobile market today.

Utilizing sophisticated computer based technology and ICOM's precision VHF engineering, the IC-H16 incorporates state-of-the-art design concepts to meet the demanding needs and requirements of the Land Mobile user.

ASSISTANCE

There are three different versions of the IC-H16. This service manual is designed to cover every version. Each model is assigned a particular number as follows.

Version No.	Version	Frequency range	Channel spacing
#01	U.S.A.	148.00 ~ 174.00MHz	25kHz
#02	U.S.A.	136.00 ~ 144.00MHz	25kHz
#03	U.K.	148.00 ~ 174.00MHz	12.5kHz

Please contact your neasrest ICOM Service center if you require assistance or information regarding the operation and capabilities of the IC-H16. Addresses are provided on the title page of this manual.

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SECTION 1 SPECIFICATIONS

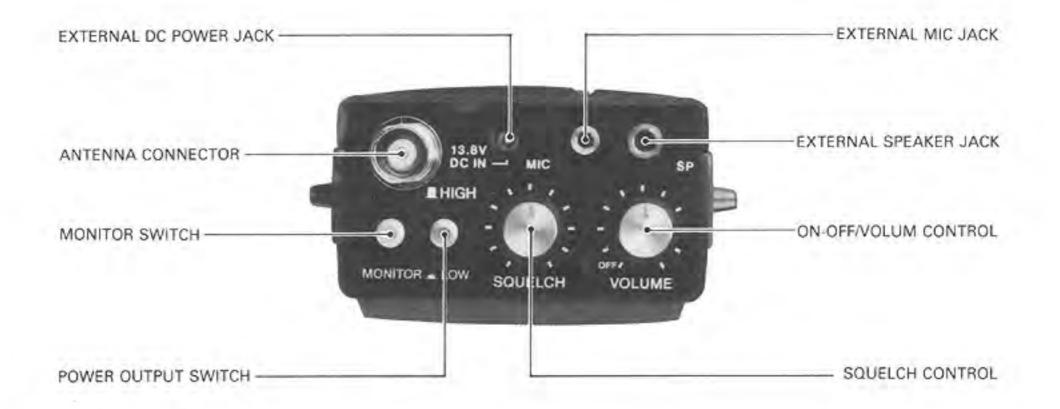
GENERAL

Frequency range	: 148.00MHz~174.00MHz (#01, #03) 136.00MHz~144.00MHz (#02)
Number of channels	: 16 channels (keyboard programmable)
Number of charmers	Simplex, semi-duplex operation
Usable temperature	: -30°C~+60°C (-22°F~+140°F)
Channel spacing	: 25kHz (#01, #02) 12.5kHz (#03)
Frequency stability	±0.0005%
Antenna impedance	50 ohms unbalanced
Power supply requirement	: 8.4V DC with IC-CM8 attendant battery pack (negative ground)
Current drain	: Transmit : 1150mA approx.
content uran	Receive : 200mA approx.
	Standby : 65mA approx.
Bindinatana	(35mA with power saver)
Dimensions	: 65(74)mm(W) × 196(207)mm(H) × 38(41)mm(D)
10000	Bracketed values include projections.
Weight	595g including IC-CM8 battery pack.
RECEIVER	
Receiving system	: Double-conversion superheterodyne
Modulation acceptance	: 16K0F3E
Intermediate frequency	: 1st: 21.8MHz
	2nd: 455kHz
Sensitivity	: Less than 0.4µV for 12dB SINAD
Audio output power	: 500mW minimum at 10% distortion with 8 ohms load.
Audio output impedance	: 8 ohms
TRANSMITTER	
Output power	: HIGH 2.5W LOW 0.5W (with IC-CM8)
	HIGH 5.0W LOW 0.5W (with IC-CM7)
Emission mode	: 16K0F3E
Modulation system	: Variable reactance frequency modulation
Microphone	: Built-in electret condenser microphone

Modulaus

1 - 1

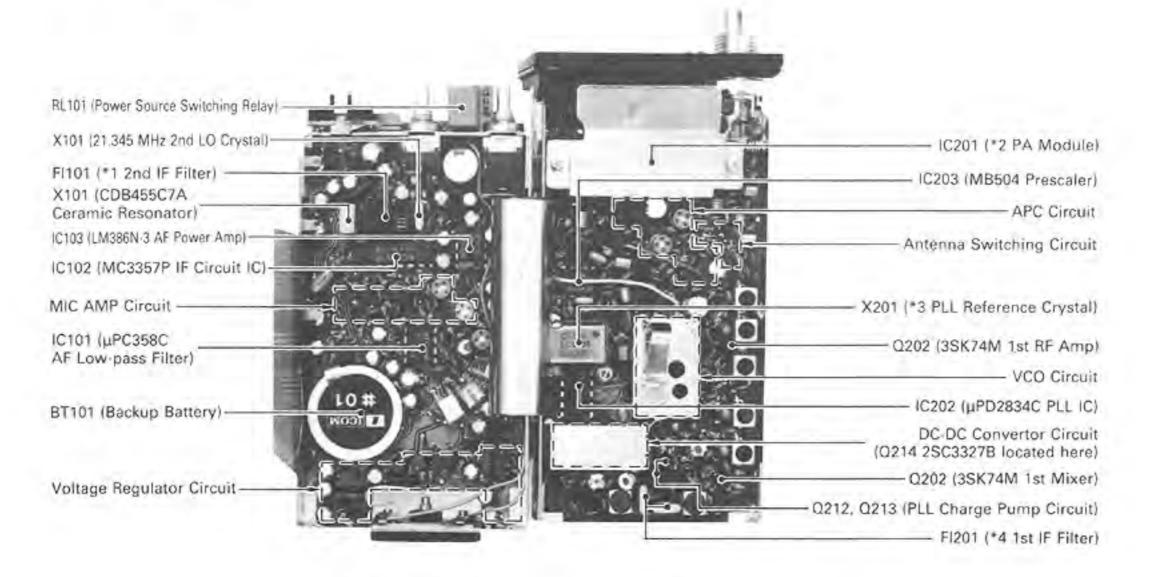
SECTION 2 OPERATING CONTROLS





SECTION 3 INSIDE VIEWS

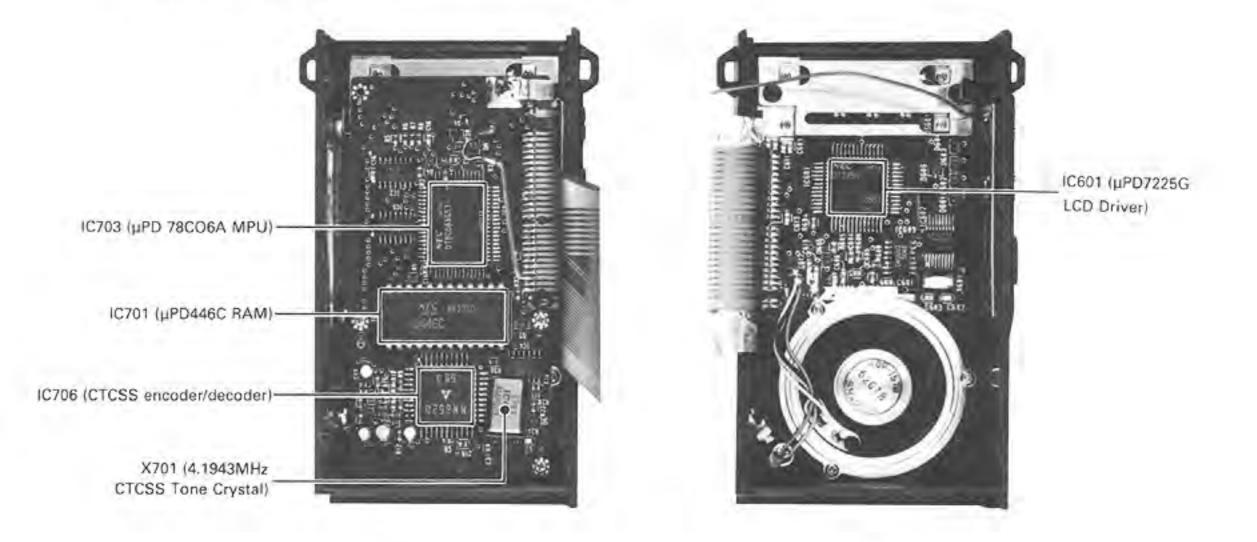
MAIN/PLL UNIT



MAIN UNIT

PLL UNIT

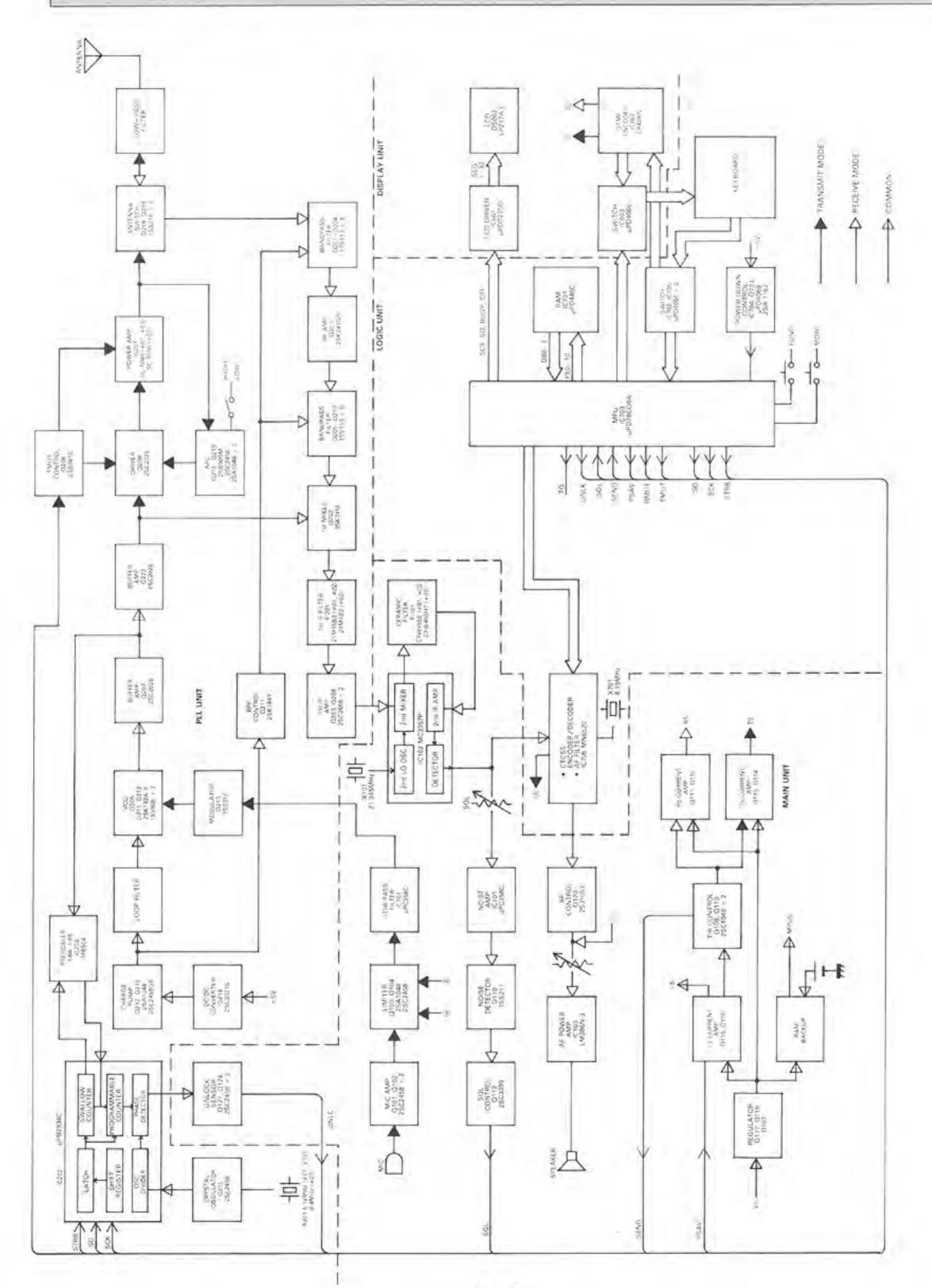
*1 FI101 CFW455E (#01, #02) CFW455HT (#03) *2 IC201 SC-1046 (#01, #03) SC-1050 (#02) *3 X201 5.12 MHz (#01, #02) 6.4 MHz (#03) *4 FI201 21M15B3 (#01, #02) 21M7B2 (#03)





3 - 1

SECTION 4 BLOCK DIAGRAM



4 - 1

SECTION 5 CIRCUIT DESCRIPTION

5 - 1 RECEIVER CIRCUITS

5 · 1 - 1 ANTENNA SWITCHING CIRCUIT

input signals from the antenna connector are fed into the antenna switching circuit through low-pass filter consisting of C270, L219, C269, L218, C268, C267 and C266 on the PLL unit. The antenna switching circuit employs a quarter wave circuit. consisting of D218, D219, C264, C265 and L217.

5 - 1 - 2 RF AMPLIFIER CIRCUIT

Signals from the switching circuit pass through bandpass filters consisting of L201, C202, D201, D202, D203, D204, C305 and L202 on the PLL unit. Signals passed through the bandpass filters are applied to the first RF amplifier, Q201 and are amplified.

Output signals from Q201 are again passed through bandpass filters which consist of L203, C209, D205, D206, L204, C212, D207, D208, D209, D210, L205 and C216 and are then reduced interference from out-of-band signals.

Diodes D201 to D210 are varactor diodes that track the bandpass filters and are controlled by the PLL lock voltage. These diodes tune the center frequency of the bandpass filters for wide bandwidth reception and a good image response rejection ratio.

Signals from the bandpass filters are fed into gate 1 of Q202. Local oscillator signals from the PLL unit also are fed into gate 2 of Q202 through C217. Q202 is a first mixer which converts RF signals into 21.8MHz the first intermediate frequency and outputs it at L206.

5 - 1 - 3 INTERMEDIATE FREQUENCY CIRCUIT

The first intermediate signal from L206 is filtered further

5 - 1 - 4 AUDIO FREQUENCY CIRCUIT

IC706 incorporates a CTCSS encoder/decoder, an AF amplifier, and a dual AF filter circuit.

The signal applied to IC706 is amplified and then exits from pin 18. This signal is amplified at Q702 through a low-pass filter consisting of R715 and C711. This low-pass filter is a de-emphasis circuit which has -6dB/oct characteristics.

Output signals from Q702 re-enter the MAIN unit and are fed into AF SWITCH (Q120). This FET cuts the AF signal when RX MUTE is operating or the squelch is closed.

The signals that enter Q120 are then fed into an AF power amplifier circuit (IC103 pin 3) through AF volume control R161. The gain of IC103 is fixed by R162 and C155 which are connected across pins 1 and 8. The speaker is driven at more than 500mW of AF output by IC103 with an 8 ohm load and 8.4V Vcc.

The power source for IC103 consists of Q123 and D113 which protect it from excess voltage, maintaining the voltage at less than 12V.

5 - 1 - 5 SQUELCH CIRCUIT

A portion of signals output from IC102 (pin 9) pass through R148, Squelch volume and is then input to active filter IC101B (pin 2) where noise signals are selected at approximately 20kHz then output from pin 1.

The noise signals are detected by D110 and are then converted to DC voltage and used as squelch control signals. This voltage is input to IC703 (pin 15) on the LOGIC unit through invertor circuit Q119, and is then output from pin 30 as R.Mute voltage.

from out-of-band interference through a matched pair of monolithic crystal filters that are FI201 and is then amplified at Q203 and Q204.

IC102 on the MAIN unit incorporates in one package a second local oscillation circuit, a second mixer, a limiter amplifier, an active filter, and a quadrature detector circuit.

The first intermediate frequency signal enters IC102 (pin 16) and mixes with a second local oscillator frequency (21.345MHz) generated by X101. The 455kHz second intermediate frequency signal is then output from pin 3. This signal passes through a high-performance ceramic filter (FI101), and is amplified at a limiter amplifier.

Output signals from the limiter amplifier are separated. One of the signal enters a quadrature detector circuit, and the other exits from pin 7. The signal output from pin 7 enters pin 8 through ceramic resonator X102, and then both signals are detected at a quadrature detector circuit inside IC102. The resulting audio signal is output from pin 9 and is then applied to IC706 (pin 29) on the LOGIC unit.

R.Mute voltage is applied to the gate of Q120 and switches AF output. Q120 also eliminates the noise from channel changing during operation. Q126 receives a strobe pulse from IC703 and applies a mute signal to Q120.

5 - 1 - 6 FIRST LOCAL OSCILLATOR CIRCUIT

The signal (114.2 ~ 152.2 MHz) generated at the VCO is amplified at Q207 on the PLL unit and is then input to gate 2 of Q202 on the RF unit through D214.

5 - 2 TRANSMITTER CIRCUITS

5 - 2 - 1 MIC AMPLIFIER CIRCUIT

The audio signal from MIC 1 or MIC 2 is amplified by a limiter amplifier circuit consisting of Q101 to Q104. This limiter amplifier circuit employs of a negative feedback circuit that has pre-emphasis characteristics between 300Hz and 3kHz with 6dB/oct.

The first mic amplifier circuit consists of a differential amplifier circuit that makes a limiter output signal in a symmetical wave form.

The output signal from the limiter amplifier is like a square wave and includes many RF signals which are fed back from the transmitter's final stage. The output signal, therefore, is fed to splatter filter circuit IC101A which reduces signals with more than 3kHz, and then applies it to the VCO for modulation.

5 - 2 - 2 BUFFER AMPLIFIER CIRCUIT

The 100MHz band is generated by the VCO and is buffered and amplified at Q207 and Q223. Output from Q223 is amplified at drive stage Q208 through D215, thus obtaining a wideband of 20mW.

5-2-3 POWER AMPLIFIER CIRCUIT

IC201 is a small-sized power module giving a stable output power of more than 5W (136 \sim 144MHz or 148 \sim 174MHz) with a driving power of 20mW from Q208.

The driving signals from Q208 are fed into IC201 (pin 1), amplified up to approximately 5W at 13.2V, and are output from pin 5.

While transmitting, Q220, D218 and D219 are activated, then L217 and C265 become parallel resonance circuits. The output power from IC201 is applied to the antenna terminal through a low-pass filter consisting of C226 to C270, L218 and L219 that filters and reduces harmonic spurious radiation.

Q206 controls the bias voltage of Q208 and IC201 to prevent unwanted emissions when switching from receive mode to transmit mode, or when the PLL is being unlocked to prevent a possible failure.

5-2-4 APC CIRCUIT

The antenna mismatching detection circuit consists of L215, C256 to C261, D216 and D217. Output voltage of the detector is a minimum value when the antenna impedance is matched at 50 ohms. However, when the antenna impedance is in a mismatched condition, the detector voltage becomes higher than it would be if the antenna were matched.

Q218 and Q219 make up the differential amplifier circuit. At the base of Q219, the bias voltage determined by R272, R276 and R274 is applied.

The voltage detected at D216 and D217 is combined by R237 and R238, and is fed into the base of Q219. If a mismatched condition occurs, the voltage at the base of Q218 will be higher than at the base of Q219. This condition will reduce the Q217 collector current and the Q216 base current, decreasing the current of Q208.

The output power of Q208 is also decreased, reducing the output power of IC201 until the base voltage of Q218 becomes equal to the base voltage of Q219.

In a matched condition, HIGH output power is determined by the value of R272. When the power switch is in the LOW position, the combination of R273 and R275 is connected in parallel with R274. R275 may then be used to set the low power.

5 - 3 PLL CIRCUITS

The PLL is designed in a way that allows the desired frequency to be generated directly by the VCO, adopting a dual modulous pre-scaler system. The PLL consists of a pre-scaler (IC203) and PLL IC (IC202). It is fed "divided by N-data" from the MPU which determines the operating frequency.

N-data is determined by dividing the desired frequency by the reference frequency. Desired frequency is the transmit frequency in the transmit mode and the first local oscillator frequency in the receive mode.

A reference frequency of 5kHz (12.5kHz #03) is obtained by oscillator Q215, X201 and the internal IC202 divider.

Signals from the VCO that are buffer amplified at Q207 are divided N times at IC203 and fed into pin 4 of IC202. Signals inside IC202 are phase detected and are lock voltages that are output from pins 12 and 13. Output voltages are applied to varactor diode D211 and D212 in the VCO circuit through a loop filter that controls the VCO frequency. Due to a no-multiplying mixing circuitry, the circuit constitution is simple and reduces spuriousness.

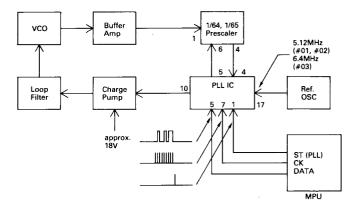


Fig. 5-1 PLL Circuit Block Diaglam

5-3-1 UNLOCK CIRCUIT

When the PLL is unlocked, pin 10 of IC202 is at a LOW voltage level. This voltage is fed into unlock detection circuits Q121 and Q124 on the MAIN unit and is then sent to the MPU on the LOGIC unit.

5 - 3 - 2 LOOP FILTER CIRCUIT

Output from pins 12 and 13 on the IC203 is fed into charge pumps, Q212 and Q213 and is then applied to a lag lead-type loop filter that consists of R248, R246, and C278. These circuits determine the characteristics of the PLL.

Output voltages from loop filter control varactor diode D211 and D212 in the VCO circuit through integral circuits R245 and C276.

5 - 3 - 3 VCO UNIT

The VCO, Q205 employs a Hartley oscillator circuit. The VCO free-run frequency is shifted by induction reactance of L221 which is changed by Q222 and D213, and is then controlled by a varactor diode. Thus a stable oscillation is achieved over a wide frequency range.

While receiving, the RS5 line is 5V, Q222 and D213 are activated, and then C236 is conneected in a parallel with D211 and D212 through C233. While transmitting, the RS5 line is 0V and then Q222 and D213 turn OFF. So C236 has no effect on the oscillastion frequency. Therefore the VCO free-run frequency while transmitting is higher than while receiving.

While transmitting, modulation signals are applied to the cathode of D211 and D212, and then its capacitance is changed, performing frequency modulation. This deviation is adjusted by R186.

5 - 4 POWER SUPPLY CIRCUITS

5 - 4 - 1 INTERNAL/EXTERNAL POWER

When using a battery pack, RL101 is OFF. When a power source having $10 \sim 16V$ is connected to the external power terminal (EXT), RL101 will be activated. The transceiver will then be operated by an external power source.

If an incorrect connection to the external power terminal (such as reversing polarities) is made, D109 will be affected, reversing its bias and preventing RL101 from being activated.

5 - 4 - 2 +5V REGULATOR CIRCUIT

The +5V voltage regulator circuit consists of Q117, Q118 and D107 where output voltage is kept at 5V constantly, even with input voltage from 5.1 \sim 16V. These transistors are connected in a complementary circuit in order to acquire a higher current amplification factor. As the temperature coefficient of the junction voltage of D108 is nearly equal to the voltage of Q117 V_{BE}, the output voltage is kept constant against temperature changes.

5 - 4 - 3 5V REGULATOR, POWER SAVE CIRCUIT

This voltage regulator circuit uses reference voltage from pin 29 of IC703 on the LOGIC unit. This circuit consists of Q115 and Q116 which are also connected in a complementary circuit in order to stabilize operations. When the power save function is activated, power save signals from pin 29 of IC703 on the LOGIC unit are applied to Q115 at intervals, thus Q115 turns ON and OFF alternately. The result is that the power save signal controls +5V and constructs the POWER SAVER.

5-4-4 T/R SWITCHING CIRCUIT

While transmitting, Q106 is activated and transfers transmit signals to the MPU. At the same time, Q107, Q108, and Q109 are also activated, and Q110 turns OFF. Q113 and Q114 are T5 voltage regulator circuit that is switched by Q109. When Q109 is activated, the T5 line operates at 5V and the R5 line at 0V. While receiving, Q106 is OFF. Q109 is then OFF and Q110 is ON, resulting in the T5 line being 0V and the R5 line 5V.

When the squelch is changed from the closed to open condition some noise will be emitted from the speaker. This phenomenon is called the squelch burst. To remove this noise from the speaker, the squelch can be controlled by a CTCSS tone.

The transmitter contains a delay circuit for the transmit carrier. The delay period for the transmit carrier is longer than that of the PTT.

In this transceiver the delay circuit consists of time constants C131 and R137 which remove the squelch burst.

5 - 4 - 5 VOX POWER SOURCE CIRCUIT

This is a current limiter that supplies a voltage to the external VOX unit, HS-10SA. Current drain of up to 5mA is acceptable. In the case of a normal load current the voltage drop through R279 is small, approximately 5V, and is fed into the VOX unit. The increase in load current leads to the increase of the voltage drop at R279. When the voltage, obtained by adding the voltage between the emitter and base of Q221 to it, is equal to the voltage between R280 and the D225 cathode, the load current is limited.

This VOX power source circuit is also a data transmit circuit when the cloning operation is activated. The base of Q217 connects through R281 to pin 28 (CPO) on IC703. CPO is the output port for cloning data and controls Q217, thus data is transferred to existence.

Cloning data exits from the mic terminal and passes through R102, R104, and control Q106 on the MAIN unit. It then enters pin 14 (SEND) of IC703 for data reception. SEND also combines a data input port.

5 - 5 LOGIC CIRCUITS

The LOGIC circuits consist of an 8 bit C-MOS MPU, a 2K C-MOS RAM, a CTCSS tone encoder/decoder, and an LCD driver. They control frequency, tone, display, etc.

5-5-1 MPU

This MPU, μ PD78C06AG, includes a 4K byte ROM and a 128 byte RAM. Following is an explanation of operations related to each port.

(1) DB 0 \sim DB 7

These are bi-directional ports, and are an 8 bit data bus. The bus transfers or receives the data to and from a 2K RAM IC chip. DB 0 to DB 3 are also used for matrix reception.

(2) PE 0 \sim PE 15

These are 16 bit ports which have address ports and output ports that are switched by the program. PE 15 is used to select signals. PE 0 to PE 10 generate address signals. PE 0 to PE 3 and PE 14 are output ports for the matrix. PE 0 is used as a switching signal for command and LCD driver data. (The matrix construction is described in Fig. 5-2.)

(3) PORTS A

These are output ports with an 8 bit latch.

• PA 7 (CS)

This is an enable signal for the LCD driver. When this port is LOW, the MPU transfers COMMAND or DATA to the LCD. (Timing charts is described in Fig. 5-3.)

• PA 4 (TMUT)

This is an output port and will be at the HIGH level position for approximately 60 milliseconds when changing from receive to transmit. If the PLL is unlocked then this port will remain at a HIGH level.

PA 3 (RMUT)

This port will be at the HIGH level position when receiving in the mute condition.

PA 2 (PSAU)

This port outputs control signals for saving power. When this port is in the LOW level position, the transceiver is in the save condition.

• PA 1 (CPO)

This port outputs cloning data. (The cloning data construction is described in Fig. 5-4.)

PA 0 (STRB)

This port outputs latch signals for PLL data.

(4) PORTS B

These ports are 8 bit bi-directional ports that change in 1 bit steps.

• PB 7 (MONI)

This is an input port for the monitor switch.

• PB 6 (T/R)

This is an output port for switching the signals of the TONE IC. While in the transmit mode, this port is at the LOW level position; in the receive mode it is in the HIGH level position. However, if the TONE number is 0, voltage signals are opposite.

• PB 0 ~ 5 (S0 ~ S5)

These are output ports for TONE data which describe TONE numbers, frequency, and data.

(5) PORTS C

These are input ports with 6 bits of data.

• PC 5 (BUSY)

This is an input port for BUSY signals from the LCD driver.

• PC 4 (TRF)

This is a T5V input port. When this port is at the HIGH level position the TX indicator is illuminated.

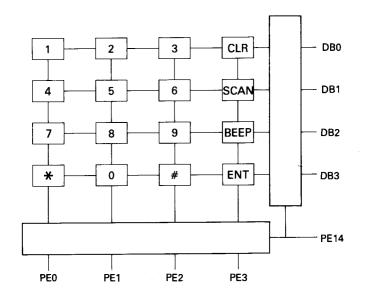
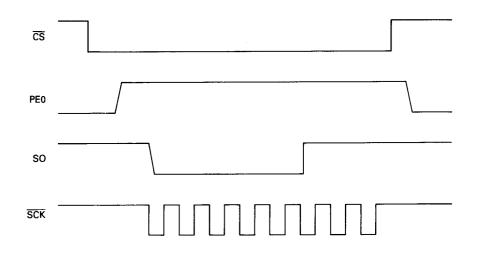


Fig. 5-2 Matrix Construction

AT COMMAND TRANSMITTING (CODE OE, OH)



AT DATA TRANSMITTING (DATA 0A, 5H)

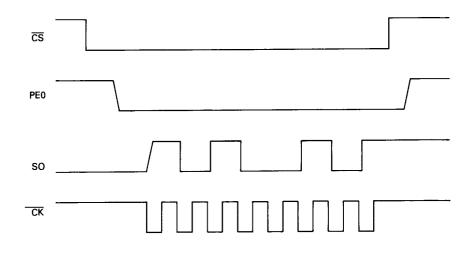
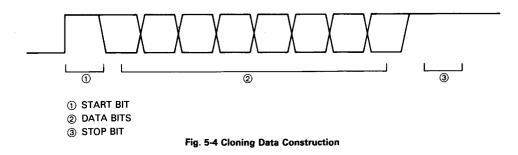


Fig. 5-3 Timing Chart of COMMAND and DATA



PC 3 (FUNC)

This is an input port of the function switch. When the function key is pressed, this port is at the LOW level position and the secondary functions of the keyboard can be selected.

When this port is in the LOW level position while power switched ON, the MPU is in the receive mode of cloning.

PC 2 (SEND)

This is a T/R switching signal input port. When this port is in the HIGH position the MPU is in transmit mode. The port is also used to input cloning signals.

PC 1 (SQL)

This is an input port for squelch signals. When the squelch is open, this port is in the HIGH level position.

PC 0 (UNLK)

This is an input port for unlocked signals. When the PLL is unlocked, this port is at a LOW level position.

(5) SERIAL PORTS

• SO

This is an output port of the shift register inside the MPU. It outputs N-data, LCD commands, and LCD data.

• SCK

This port outputs timing signals of data for transfer to the SO port. SO is altered by the trailing edge of the \overline{SCK} signal.

(6) OTHERS PORTS

• INT 0

This is an input port for detector signals of the TONE IC. When this port is at the HIGH level position the CALL indicator is illuminated.

INT 1

This is an input port for stand-by signals. When the power switch is OFF this port is in the HIGH level position. The LCD then is not illuminated and each port is initialized.

• TO

This port outputs a BEEP sound.

RD

This port outputs timing signals when the MPU receives data (reading) to the RAM IC chip.

WR

This port outputs timing signals when the MPU transfers data from (writing) the RAM IC chip.

5-5-2 RAM

 μ PD446C is a 2048 word 8 bit C-MOS RAM IC chip. This RAM memorizes operating channels, PLL T/R N-data, TONE numbers, shift frequencies, TONE-data tables, etc. The data are written or read to addresses which are selected by PE 0 to PE 10 of the MPU. Writing and reading timing depend on ports RD and WR.

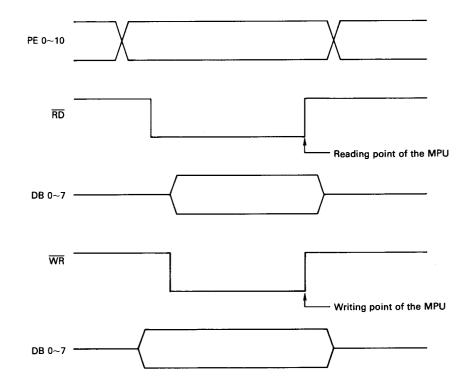


Fig. 5-5 Timing Chart of Memory Reading/Writing

5-5-3 RESET CIRCUIT

After the circuit is switched ON, the +5V line becomes 5V and Q703 is activiated. The collector of Q703 thus is at the HIGH level position. Pin 12 of IC704E is in the LOW level position and pin 10 of IC704D is changed from LOW level to HIGH. The result is that the MPU and the LCD driver are reset.

At the time the power switch is turned off, Q703 also is OFF. Pin 12 of IC704E then is in the HIGH position and is applied to INT 1 of the MPU, resulting the MPU becomes stand-by operate.

5-5-4 DISPLAY CIRCUIT

IC602, in the DISPLAY unit is the LCD driver, and segments on the LCD are displayed with 1/2 bias and 1/2 duty conditions. The bias voltage is generated via the dividing resistor which consists of R605, R606 and R607. Output from CM1, CM2, and S0 to S31 on the IC601 drive the LCD segments.

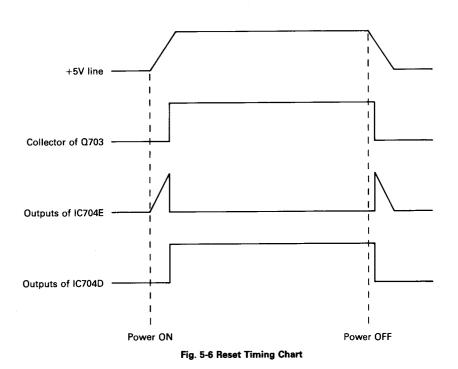
5-5-5 DTMF CIRCUIT

IC602, the DTMF encoder, generates tone signals that match DTMF telephone dialing tones. While transmitting, Q704 will be activated, thus sending voltage to IC602 and to the CONT of IC603.

When there is input from the keyboard, the proper frequency dividing ratio which divides X601 is selected to output a set of audio frequencies.

5-5-6 CTCSS CIRCUIT

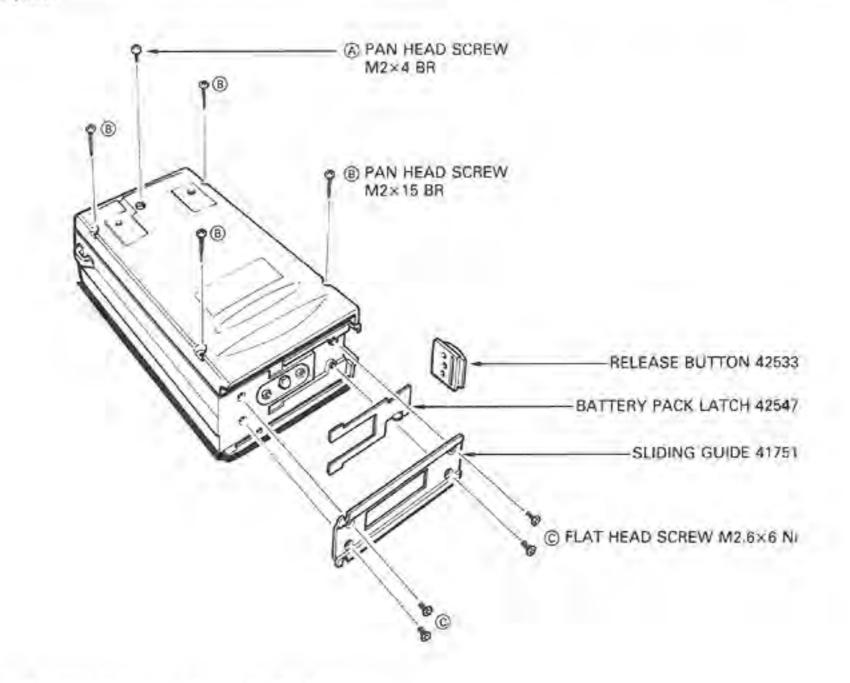
IC706 generates 37-type tones of programmable CTCSS encoder/decoder. When a tone number is set, data is sent to encoder/decoder. When a tone number is set, data is sent to IC706 from the MPU (S0 ~ S5). The \overline{T}/R port is a switching port for transmitting and receiving for IC706. When this port is in the LOW position, IC706 is in the transmit mode, and when the port is in the HIGH position IC706 is in the receive mode. However, while transmitting with tone number 0, the \overline{T}/R port of IC703 is in the HIGH position, and thus no tone signal is output from IC706.



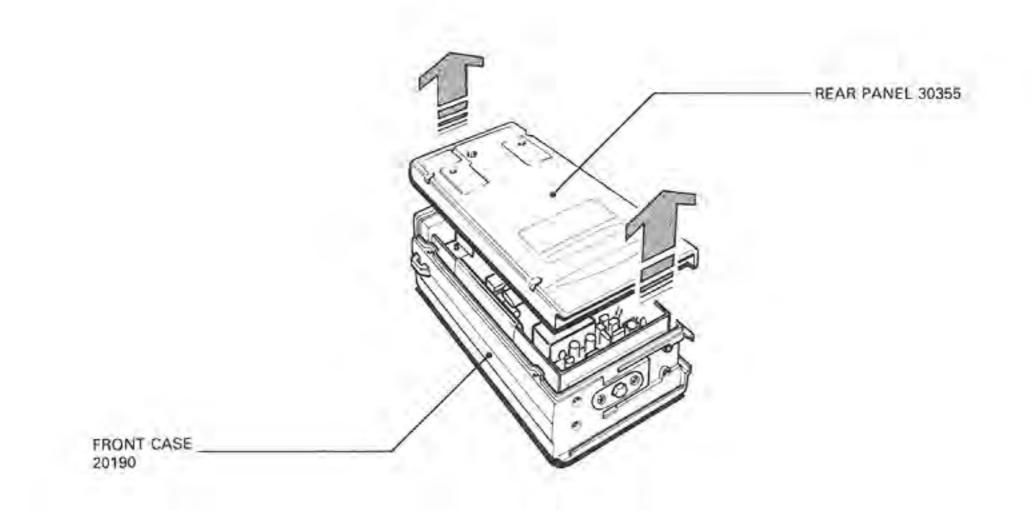
SECTION 6 MECHANICAL PARTS AND DISASSEMBLY

6 - 1 DISASSEMBLY OF THE CASE

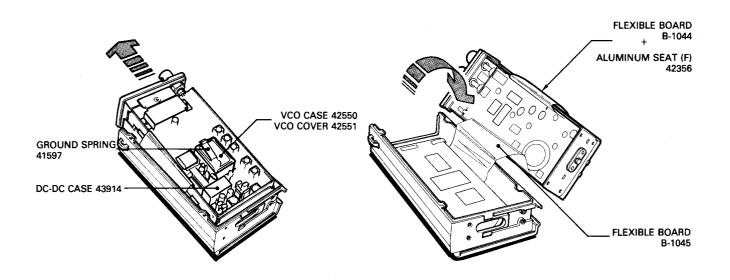
- 1. Turn the POWER SWITCH OFF and remove the battery pack.
- Remove screw (A) and four screws (B) on the rear panel, and four screws (C) on the bottom as shown in the figure.



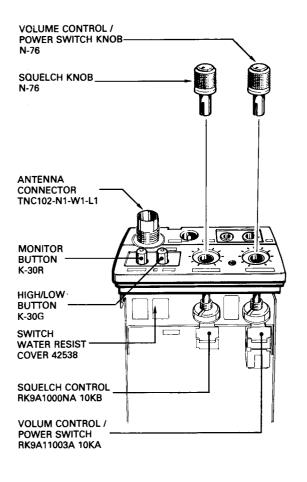
3. Remove the rear panel as shown in the figure.

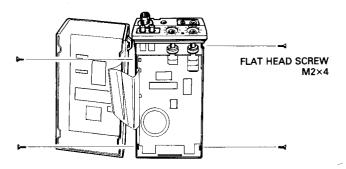


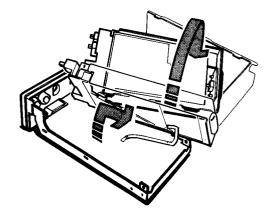
4. Slide the inner frame upward slightly as shown in the figure, and lift the frame away from the front cover. At this time, be careful not to damage the flexible board.



5. To open the chassis, remove the two knobs on the top panel (VOLUME and SQUELCH) and press IN the MONITOR and HIGH/LOW buttons. After unscrewing the four screws on the sides of the chassis, open the chassis as shown in the figure.



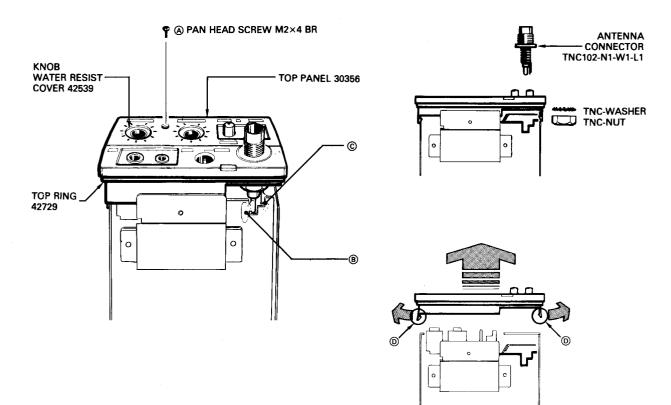




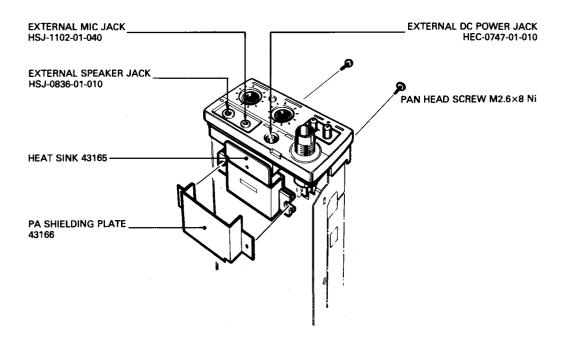
6 - 2 DISASSEMBLY OF THE TOP PANEL

- 1. Remove the screw (A).
- 2. Remove the TNC-NUT and the TNC-WASHER.
- 3. Remove the ANTENNA CONNECTOR by unsoldering point (B) on the parts side and point (C) on the soldering side of the PLL board.
- 4. Remove the TOP PANEL by slightly prying outward on both sides tabs (points (20)) of the TOP PANEL.

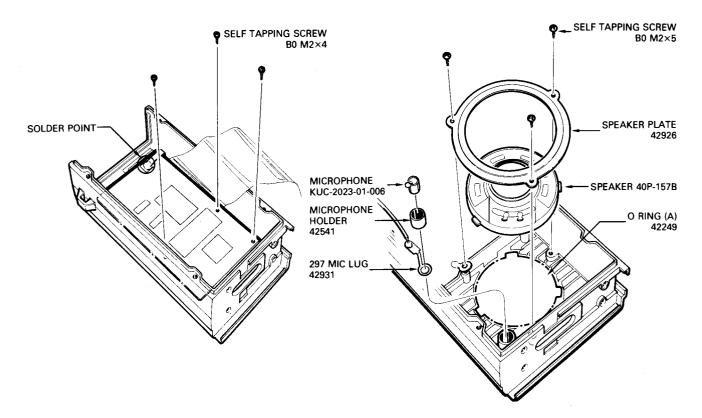
See the diagram below. Be careful not to break the tabs.



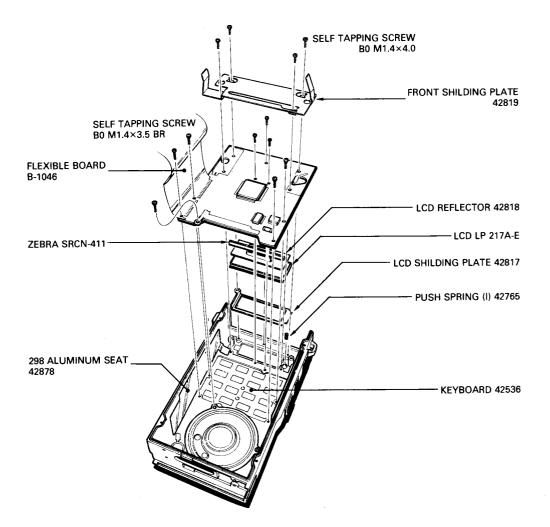
6 - 3 PA AND EXTERNAL JACK ASSEMBLY



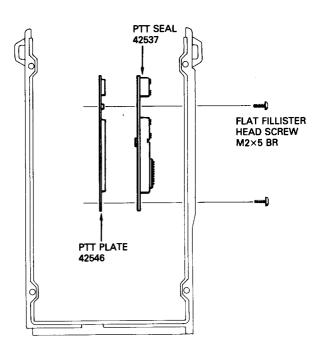
6 - 4 SPEAKER AND MICROPHONE ASSEMBLY



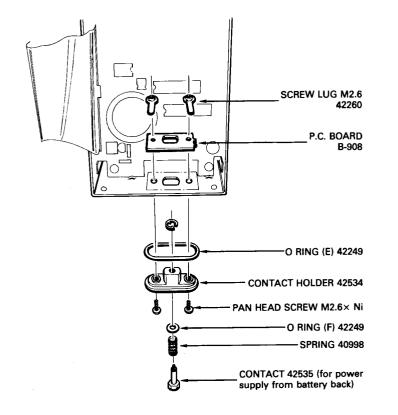
6 - 5 DISPLAY UNIT AND LCD ASSEMBLY



6 - 6 PTT SPRING ASSEMBLY



6 - 7 UNIT BOTTOM ASSEMBLY





- SOLDER POINT CAUTION: Solder only for a short time to avoid damaging the CONTACT HOLDER

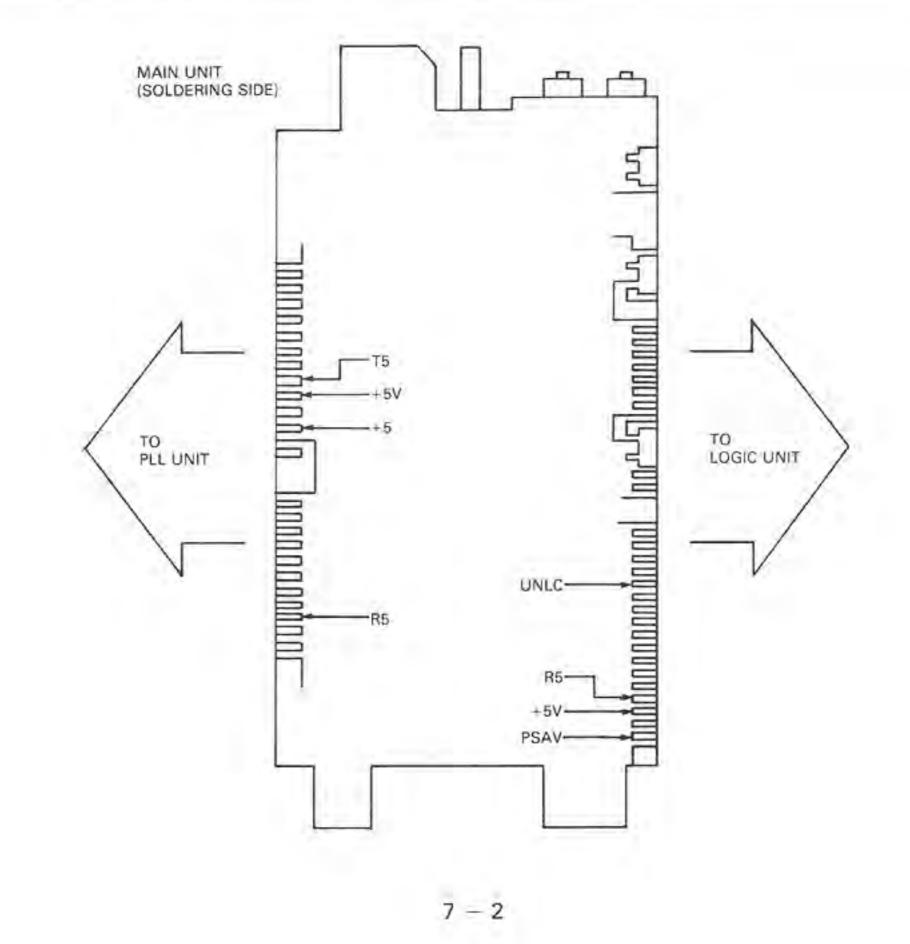
SECTION 7 MAINTENANCE AND ADJUSTMENT

7 - 1 PREPARATION BEFORE SERVICING

- Detach the power cord and turn OFF the power switch before performing any work on the transceiver.
- 2. Do not short circuit components while making adjustments.
- 3. Use an insulated tuning tool for all adjustments.
- 4. Do not force any of the variable components. Tune them slowly and smoothly.
- Follow the instructions exactly. If an indicated result is not obtained, repeat the instruction until the correct result is obtained.
- Check the condition of connectors, solder joints and screws when adjustments are complete. Confirm that components do not touch each other.
- There are several versions of this transceiver. Adjustment procedures and results may differ for each version. Be certain to follow the correct procedure for the transceiver you have.
- Confirm defective operation of the transceiver first when checking an out-of-service unit. Verify that
 external sources do not cause the problem.
- 9. Use the correct tools and test equipment.
- Remove the transceiver case as shown on Page 6-1.
 NOTE: Do not damage the flexible printed circuit when removing the case.
- 11. Remove the four screws to open the hinged chassis as shown on Page 6-2.
- For transmission problems, attach a dummy load to the antenna connector. For reception problems, attach an antenna or signal generator to the antenna connector. Do not transmit into the signal generator.
- 13. Recheck for the suspected malfunction with the power switch on.
- Check the defective circuit. Measure the DC voltages of the collector, base and emitter of each transistor.
- It is convenient to short circuit an accessory mic connector plug and insert it into the microphone
 jack when troubleshooting the transmitter.

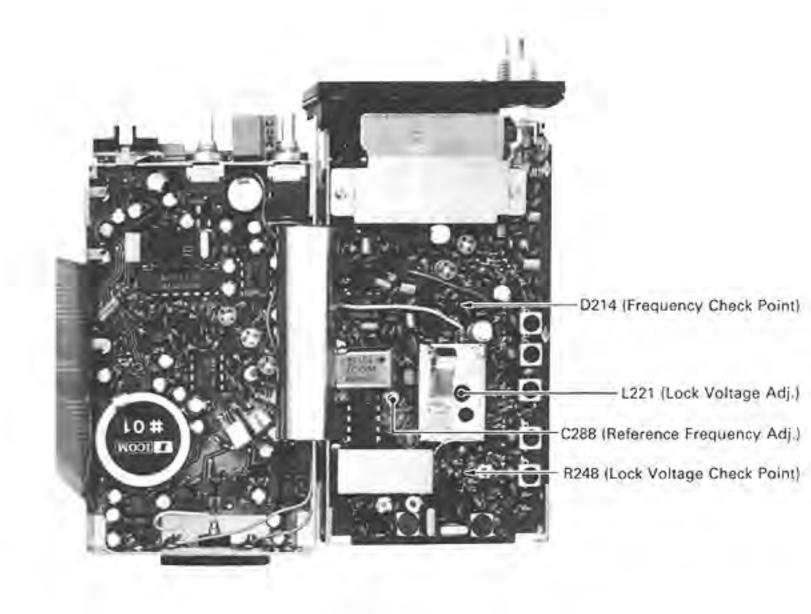
7 - 2 POWER SUPPLY CHECKES

	Ű	NSTRUMENTS REQUIRED			CONNECTIONS	3	
OUTPL CURRE RF POWE MEASL	TER	JLATED POWER SUPPLY TAGE : DC 13.2V PACITY : 2A TER (TERMINAND TYPE) RANGE : 0~5W MINIMUM : AT LEAST 180MHz : 50 Ω : LESS THAN 1:1.2 ANCE : 50k Ω/V DC OR BET		(2) RF POW METER		(1) VOLTAGE REGULAT POWER S	ED
			ME	EASUREMENT		ADJUSTN	MENT POINT
ADJUSTME	NT	ADJUSTMENT CONDITIONS	UNIT	EASUREMENT	VALUE	ADJUSTN	MENT POINT
ADJUSTME +5V	NT 1	ADJUSTMENT CONDITIONS			VALUE 5V		I
Participation of		And the second second second second	UNIT	LOCATION	1.1.1.1		ADJUST
+5V	1	Receive mode	UNIT	LOCATION See diagram	5V		ADJUST Verify
+5V R5	1	Receive mode Receive mode	UNIT MAIN MAIN	LOCATION See diagram See diagram	5V 5V		ADJUST Verify Verify
+5V R5 PSAV	1 1 1	Receive mode Receive mode Receive mode	UNIT MAIN MAIN MAIN	LOCATION See diagram See diagram See diagram	5V 5V 5V		ADJUST Verify Verify Verify



7 - 3 PLL ADJUSTMENT

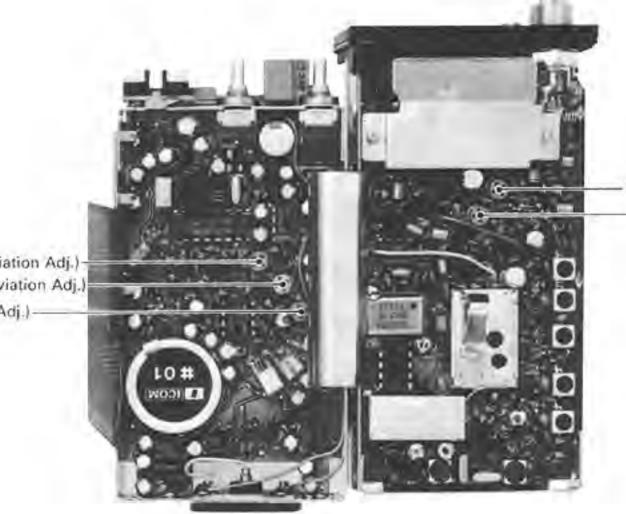
		INSTRUMENTS REQUIRED			CONNECTIONS		
OUTPU CURRE CURRE MEASI FREQU IMPED SWR (3) VOLTME INPUT	TER IMPEI NCY C	ELESS THAN 1:1.2 DANCE : 50k Ω/V DC OR BET COUNTER RANGE : AT LEAST 180MHz : BETTER THAN ±1PI		(2) RF PO METE (3) VOLTMETER (4) FREQUENCY COUNTER		(1) VOLTAGE REGULATED POWER SUPPLY	
			-	MEASUREMENT		ADJUSTMENT POINT	
ADJUSTME	(N)	ADJUSTMENT CONDITIONS	UNIT	LOCATION	VALUE	UNIT	ADJUST
LOCK VOLTAGE	1	 Operating frequency: 148.00MHz (#01, #03) 136.00MHz (#02) HIGH/LOW POWER SWITCH: LOW 	PLL	Connect a voltmeter be- tween R248 and GROUND.	4.0V (#01, #03) 2.0V (#02)	PLL	L221
	2	 Operating frequency: 174.00MHz (#01, #03) 144.00MHz (#02) Transmit mode 	PLL		bellow 16V		Verify
REFERENCE			PLL	Connect a frequency coun- ter to cathode of D214.	126.200 MHz (#01, #03) 114.200 MHz (#02)	PLL	C288
	2	 Operating frequency: 174.00MHz (#01, #03) 144.00MHz (#02) Transmit mode 			174.00 MHz (#01, #03) 144.00 MHz (#02)		Verify



7 - 4 TRANSMITTER ADJUSTMENT

		INSTRUMENTS REQUIRED			CONNECTIONS			
· OUTPL	UT VO	SULATED POWER SUPPLY LTAGE : DC 13.2V APACITY : 2A			(1) VOLTAGE			
MEASE	URING	TER (TERMINAND TYPE) S RANGE : 0~5W MINIMUM : AT LEAST 180MH : 50Ω : LESS THAN 1:1.2	z		AEGULATED POWER SUPPLY			
 (3) AUDIO G OUTPL OUTPL DISTO 	JT FRI	EQUENCY : 50~3000Hz VEL : 0~200mV		(2) RF POWER METER		-	(3) AUDIO GENERATO	
(4) AMMETE • MEASE		RANGE : 0-2A			<u><u><u></u><u></u><u></u><u></u><u></u><u></u><u></u><u></u><u></u><u></u><u></u><u></u><u></u><u></u><u></u><u></u><u></u><u></u></u></u>		Lassanti	
(5) AC MILL • MEASU		METER BRANGE ; 10mV~2V					T.	
MEASI EQUIPI DE-EM (7) DIRECTIO	JENCY URING PED F PHAS	MINIMUM : AT LEAST 180MH RANGE : 0~±10kHz ILTERS : HPF OFF LPF 20kHz		(6) FM DEVIATION METER		0	(5) AC MILLIVOL METER	
			1	MEASUREMENT		ADJUST	MENT POIN	
ADJUSTME	NT	ADJUSTMENT CONDITIONS	UNIT	LOCATION	VALUE	UNIT	ADJUS	
OUTPUT POWER SET	1	 Operating frequency: 161.00MHz (#01, #03) 140.00MHz (#02) HIGH/LOW POWER SWITCH: HIGH Transmit mode 	Top panel	Connect a power meter to ANTENNA CONNECTOR. Connect an ammeter in series between the power supply and the transceiver.	5W (at 13.2V) Less than 1.4A 3W (at 8.4V) Less than 1.25A	PLL	R272	
	2	HIGH/LOW POWER SWITCH: LOW			0,5W Less than 0.55A	PLL	R275	
VERIFY OUTPUT POWER AT THE BAND EDGES	ER AT BAND	PUT ER AT BAND	 Operating frequency: 148.00MHz and 174.00MHz (#01, #03) 136.00MHz and 144.00MHz (#02) HIGH/LOW POWER SWITCH: HIGH 	Top panel	Connect a power meter to ANTENNA CONNECTOR.	4.5~5.5W (at 13.2V) 2.5~3.5W (at 8.4V)		Verify
	2	2 • Operating frequency: 148.00MHz and 174.00MHz (#01, #03) 136.00MHz and 144.00MHz (#02) • HIGH/LOW POWER SWITCH: LOW			0.4–0.6W on both upper and lower band edges			
DEVIATION	T	 Operating frequency: 161.00MHz (#01, #03) 140.00MHz (#02) HIGH/LOW POWER SWITCH: HIGH Apply AF signal 1kHz/170mV to MIC CONNECTOR. Transmit mode 	Top panel	Connect a deviation meter to ANTENNA CONNECTOR through the attenuator.	±4.0kHz (#01, #02) ±2.0kHz (#03)	MAIN	R186	
	2 • Apply AF signal 1kHz/17mV (20dB down) to MIC CON- NECTOR. • Transmit mode				±3.0kHz~±4.0kHz (#01, #02) ±1.5kHz~±2.0kHz (#03)		Verify	
	3	 Operating frequency: 148.00MHz and 174.00MHz (#01, #03) 136.00MHz and 144.00MHz (#02) 			Less than ±4.6kHz (#01, #02) Less than ±2.3kHz (#03)	MAIN	Verify	

			1	MEASUREMENT	VALUE	ADJUSTMENT POINT	
ADJUSTMENT		ADJUSTMENT CONDITIONS	UNIT LOCATION		VALUE	UNIT	ADJUST
VERIFY TRANSMIT S/N RATIO	1	the providence of the second		Recording the reading			
	2	 Apply no signal to MIC CON- NECTOR. 			Recording the rea Verify that the rec STEP 2) must be g 35 dB (#03).	orded ratio (S	ee STEP 1 and 0 dB (#01, #0)
CTCSS DEVIATION	1	 Operating frequency: 161.00MHz (#01, #03) 140.00MHz (#02) Tone number: 01 Apply no signal to MIC CON- NECTOR. Transmit mode 	Top panel	Connect a deviation meter to ANTENNA CONNECTOR through the attenuator.	±0.75kHz (#01, #02) ±0.3kHz (#03)	MAIN	R115
	2	 Operating frequency: 148.00MHz and 174.00MHz (#01, #03) 136.00MHz and 144.00MHz (#02) Tone number: 01 and 37 Apply no signal to MIC CON- NECTOR. 			±0.5~±1.0kHz (#01, #02) ±250~±500Hz (#03)		Verify
DTMF OPERATION AND DEVIATION	1	 Operating frequency: 161.00MHz (#01, #03) 140.00MHz (#02) Tone number: 01 and 37 Apply no signal to MIC CON- NECTOR. Push and hold PTT SWITCH then push ENT key. 		Rlease the [PTT] SWITCH to check the transmit hold- ing time	Keep the trans- mit mode for approx. 1 second.		Verify
	2	 Push and hold the [PTT] SWITCH then push ENT key for a while. 	Top panel	Connect a deviation meter to ANTENNA CONNECTOR through the attenuator.	±3.5kHz (#01, #02) ±1.75kHz (#03)	MAIN	R112
	3	 Push and hold the [PTT] SWITCH then push each on the KEYBOARD. 	Front panel		To verify each key's tone sound from the speaker.		



- R272 (High Power Adj.) - R275 (Low Power Adj.)

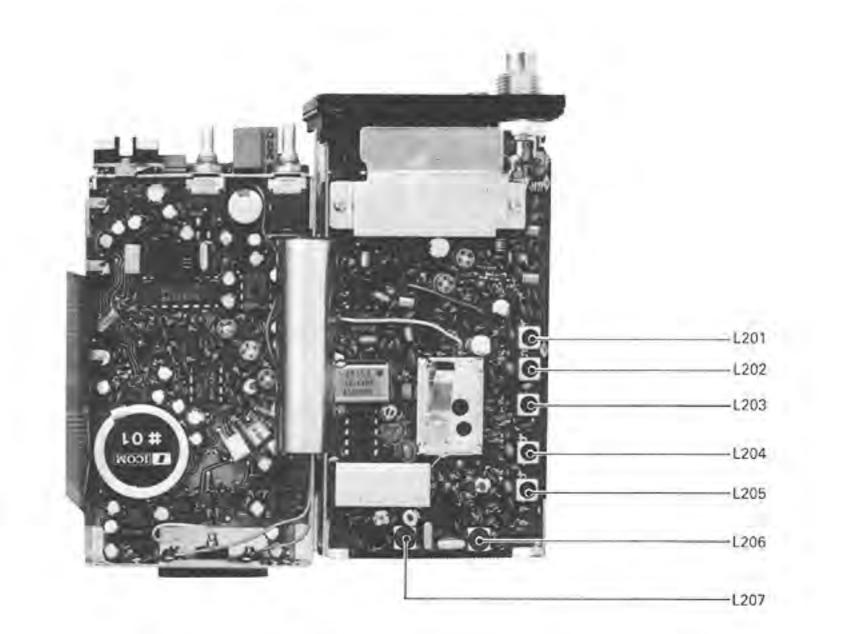
181

R112 (DTMF Deviation Adj.)-R115 (CTCSS Deviation Adj.) R186 (Deviation Adj.)

7 - 5 RECEIVER ADJUSTMENT

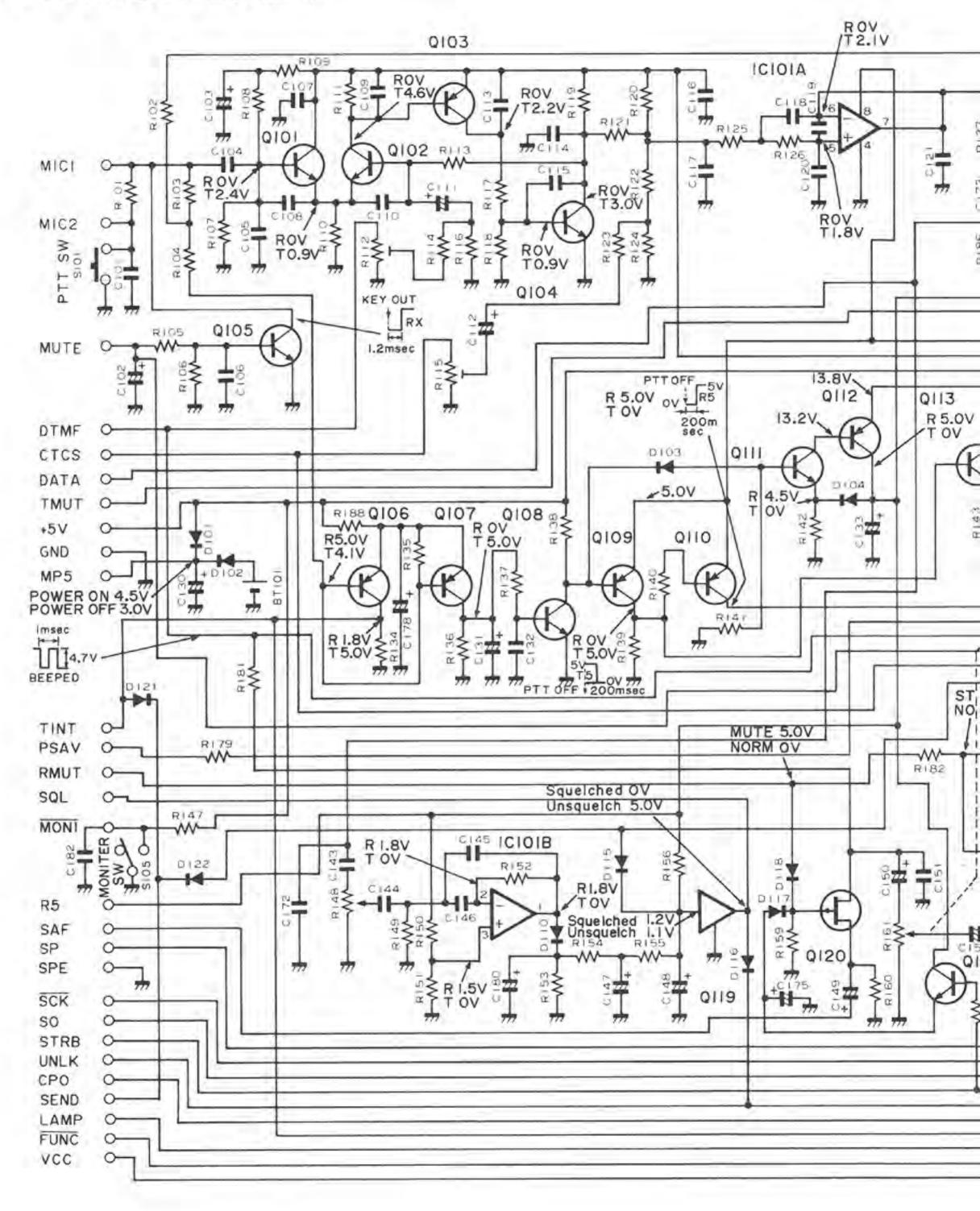
1			INSTRUMENTS REQUIRED			CONNECTIONS		
(1)	VOLTAGE • OUTPUT • CURREN	VO				(1) VOLTAGE	(i)	6) XTERNAL
(2)	OSCILLOS • FREQUER • MEASUR	VCY	RANGE : DC-20MHz			POWER SUPPLY		PEAKER
(3)	AC MILLIVO				(4) SIGNAL			
 MEASURING RANGE : 10mV-10V (4) SIGNAL GENERATOR FREQUENCY RANGE : 130~180MHz OUTPUT LEVEL : 0.1µV~32mV 			RANGE : 130~180MHz		GENERATOR	Ainn	(2) OSCI	LLOSCOPE
(5)	DISTORTIO • FREQUEN • MEASUR	NCY	RANGE : 1kHz±10Hz		(7) AUDIO GENERATOR		(3) AC MIL	LIVOLT
(6)	EXTERNAL IMPEDAN		EAKER : 8Ω				ME	TER
(7)	AUDIO GEN • QUTPUT • OUTPUT • DISTORT	FRE	QUENCY : 50~3000Hz EL : 0~200mV				(5) DIST MET	ORTION ER
					MEASUREMENT	al lander	ADJUSTMENT POIN	
A	DJUSTMEN	F	ADJUSTMENT CONDITIONS	UNIT	LOCATION	VALUE	UNIT	ADJUS
SENSITIVITY		 Operating frequency: 161.00MHz (#01, #03) 144.00MHz (#02) MONITOR SWITCH: ON SQUELCH: Open Apply RF signal to ANTENNA CONNECTOR. Level: 0.32µV (-97dBm) Dev.: ±3.5kHz (#01, #02) ±1.75kHz (#03) Mod.: 1kHz 		Top panel	Connect a distortion meter to the EXTERNAL SPEAKER JACK with an 8Ω load.	distortion level	PLL	
1		Ì.	NOTE: Adjust coils as above for	r 2 or 3 times.				
	SITIVITY HE BAND	1	 Operating frequency: 148.00MHz and 174.00MHz [#01, #03) 136.00MHz and 144.00MHz (#02) Apply RF signal to ANTENNA CONNECTOR. Level: 0.4µV (-115dBm) Dev.: ±3.5kHz (#01, #03) ±1.75kHz (#02) 	Top panel	Connect a distortion meter to the EXTERNAL SPEAKER JACK with an 8Ω load.	Less than 0.4µV for 12dB SINAD on both upper and lower band edges.		Verify
TONE SQUELCH SENSITIVITY		H 161.00MHz (#01, #03)		Top panel	Connect a speaker to the EXTERNAL SPEAKER JACK.	No sound from the speaker		Verify
		Mod.: 1kHz 2 • Apply RF signal to ANTENNA CONNECTOR. Level: 0.4μV (-115dBm) Dev.: ±3.5kHz (#01, #02) ±1.75kHz (#03) Mod.: 67Hz				Receive signal sound from the speaker "CALL" INDICATOR lights up.		Verify

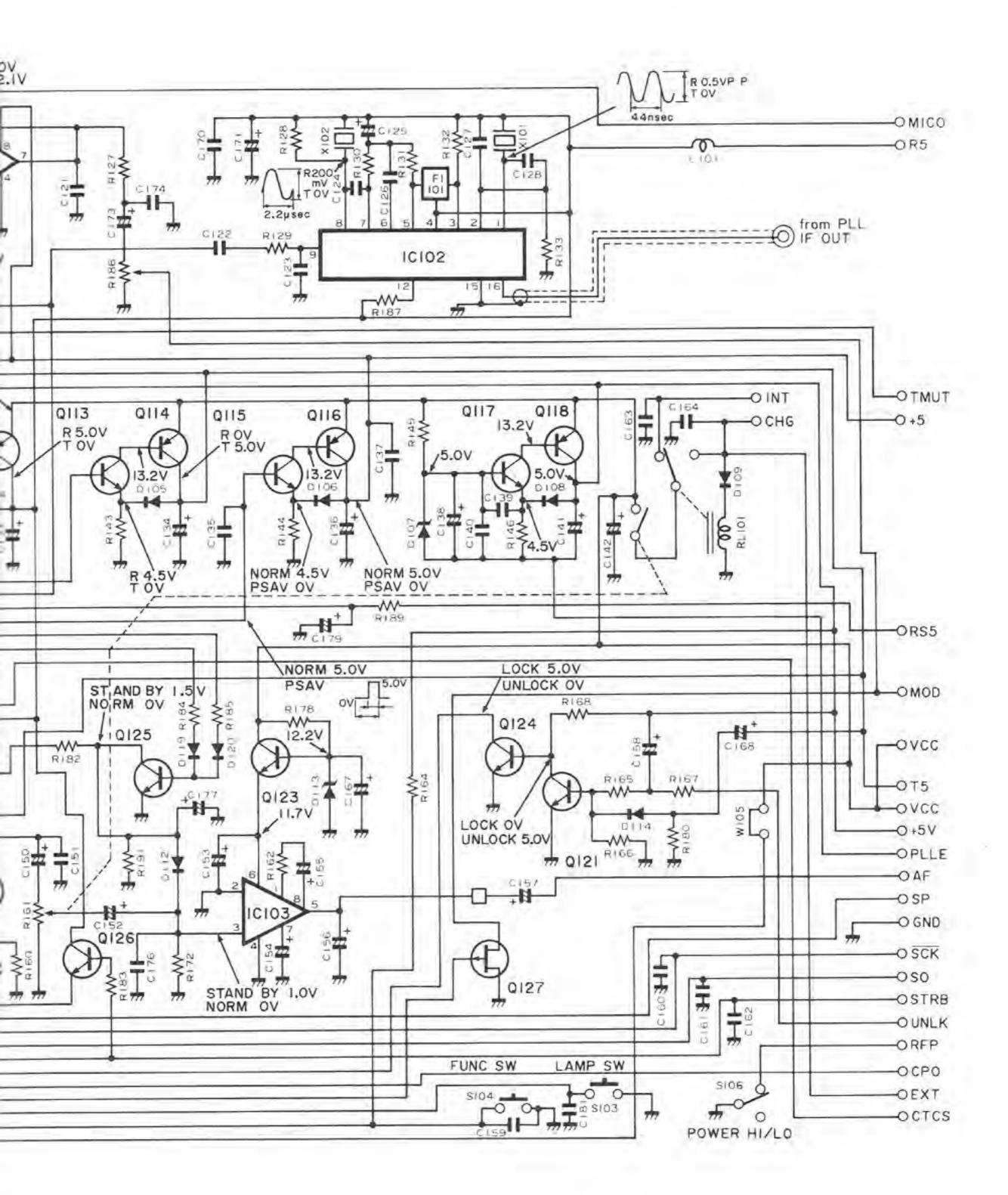
ADJUSTMENT			1	MEASUREMENT	unie	ADJUSTMENT POINT	
		ADJUSTMENT CONDITIONS	UNIT LOCATION		VALUE	UNIT	ADJUST
AF OUTPUT	1	 Apply RF signal to ANTENNA CONNECTOR. Level: 32µV (-77dBm) Dev.: ±3.5kHz (#01, #02) ±1.75kHz (#03) Mod.: 1kHz MONITOR SWITCH: ON 	Top panel	Connect an AC millivoltmeter to the EXTERNAL SPEAKER JACK with an 8 Ω load.	Greater than 2V at 10% distortion		Verify
TIGHT SQUELCH SENSITIVITY	1	 SQUELCH CONTROL: MAX. C.W. Apply RF signal to ANTENNA CONNECTOR. Level: Approx. 1µV (-107dBm) Dev.: ±3.5kHz (#01, #02) ±1.75kHz (#03) Mod.: 1kHz 	Top panel	Connect a speaker to the EXTERNAL SPEAKER JACK.	Squelch opens		Verify

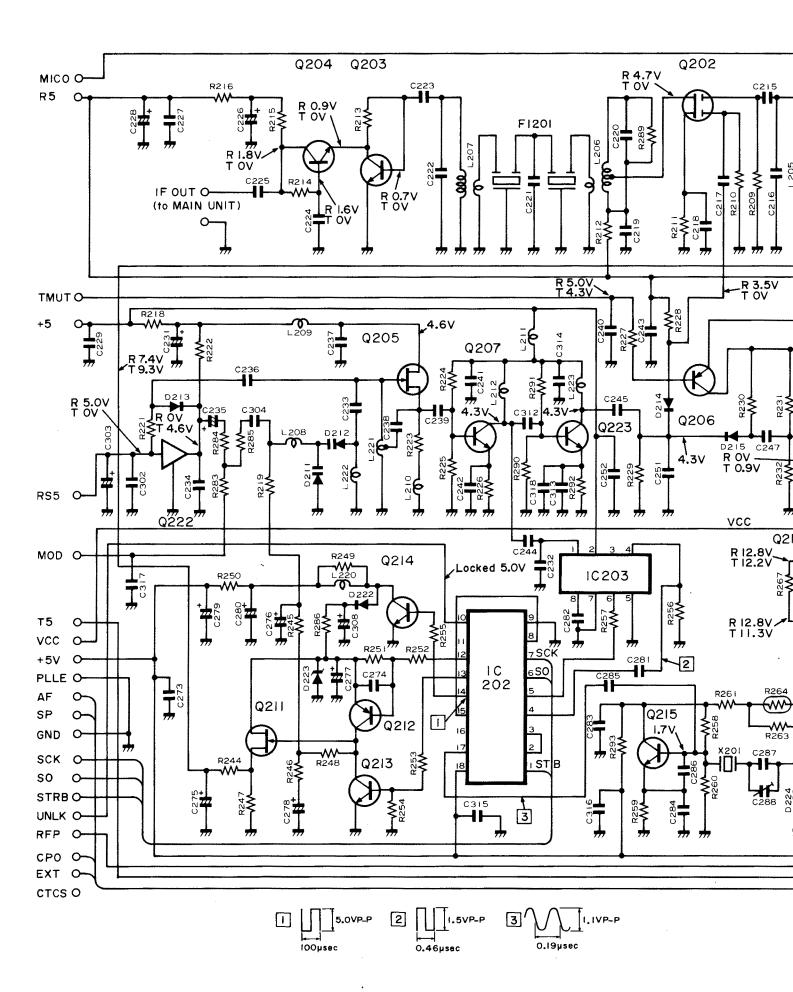


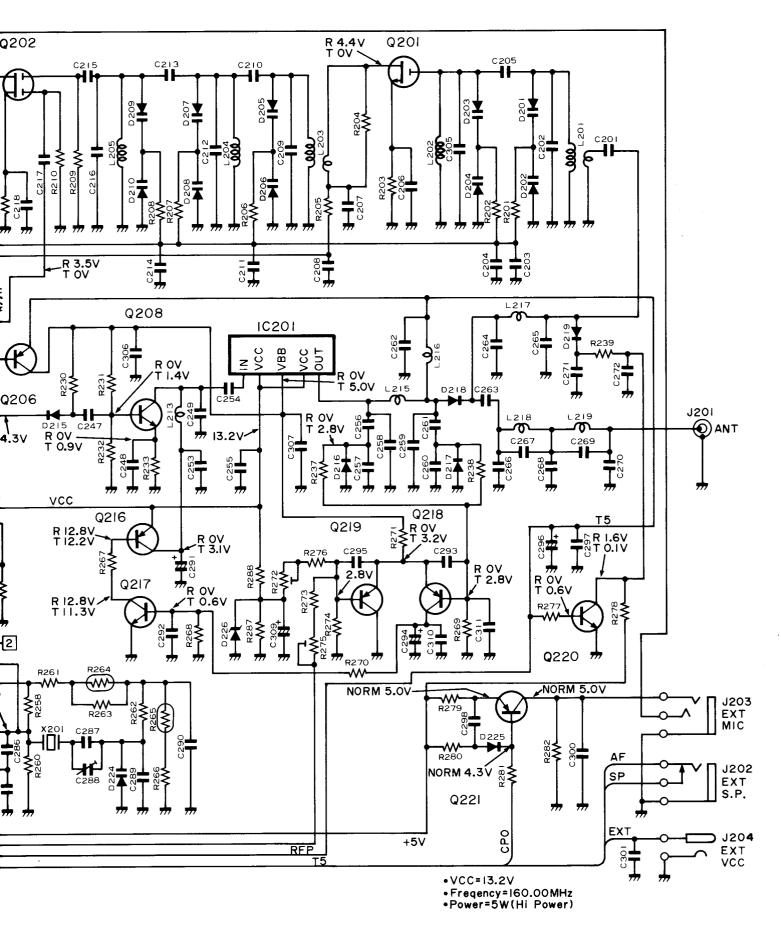
SECTION 8 VOLTAGE DIAGRAMS

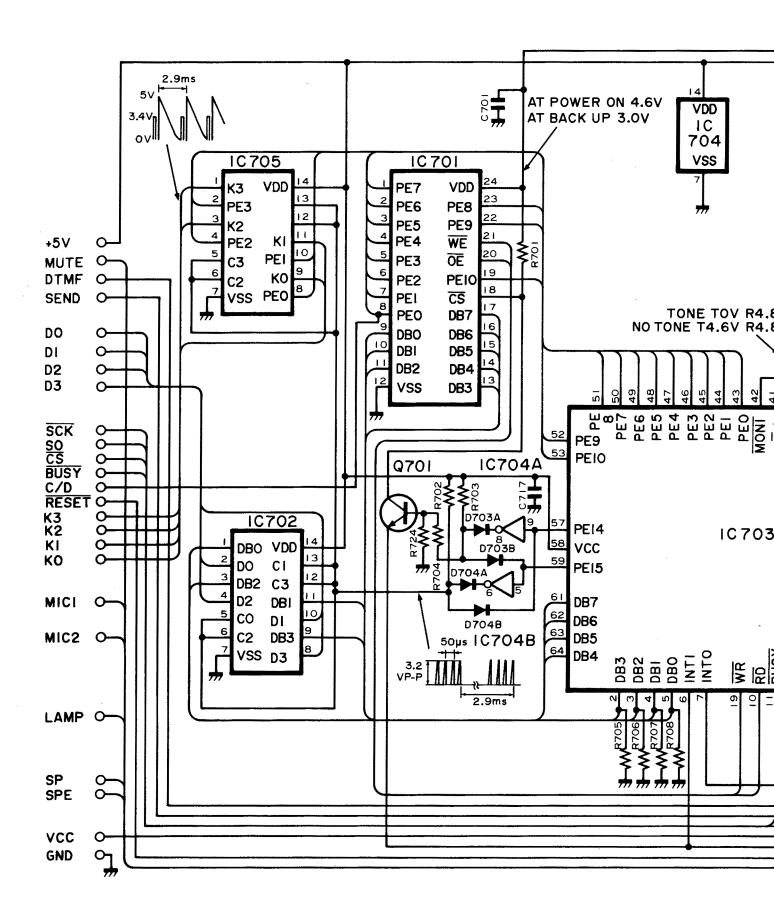
8 - 1 MAIN UNIT VOLTAGE DIAGRAM

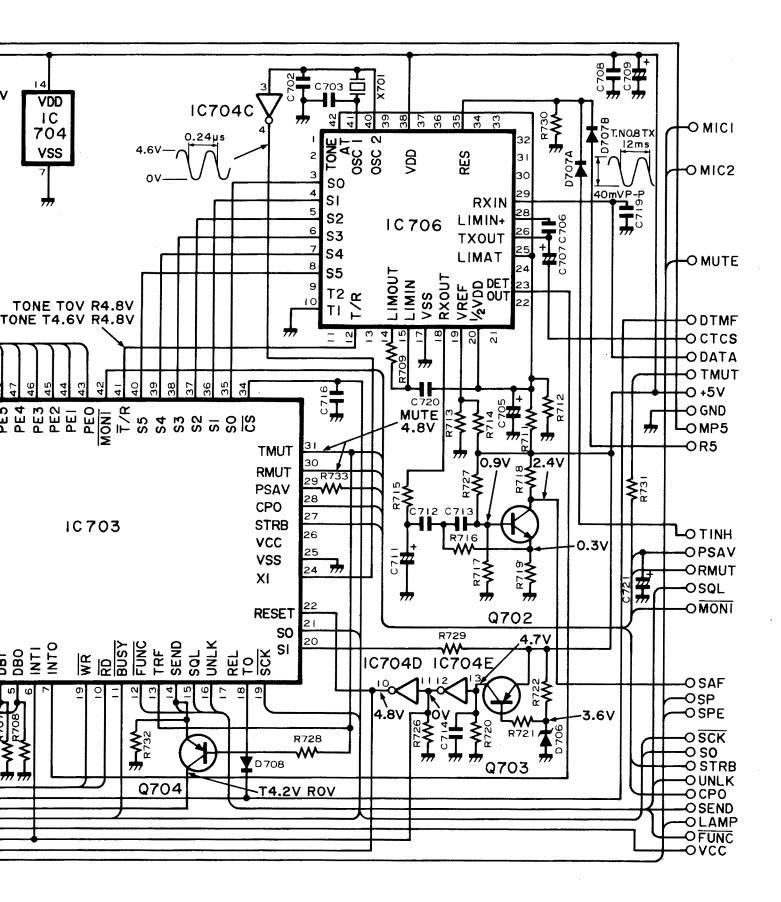


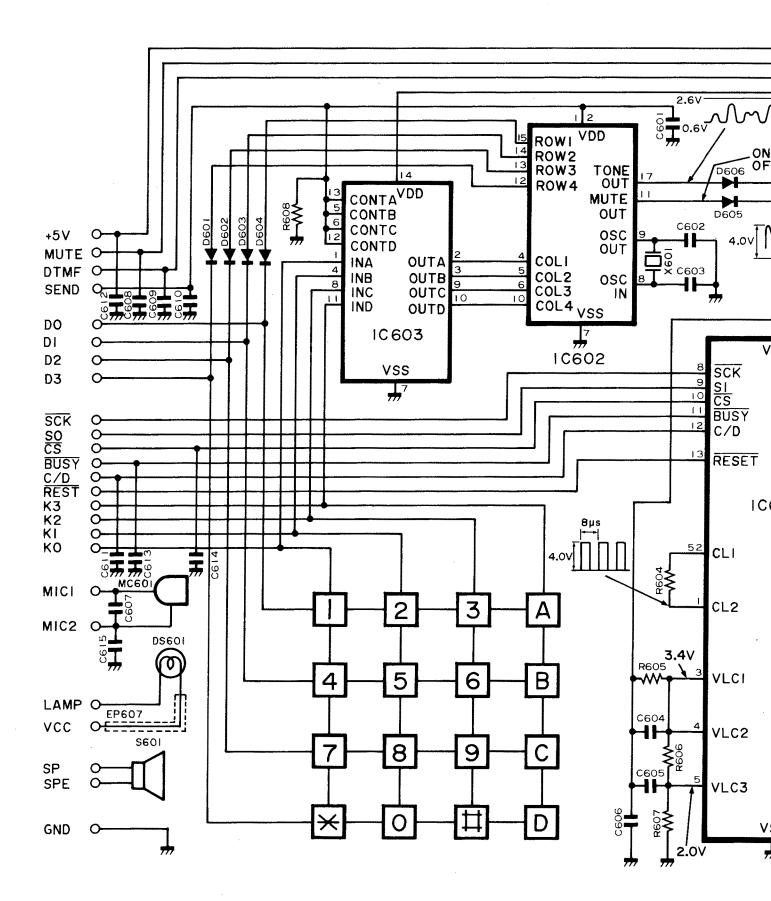


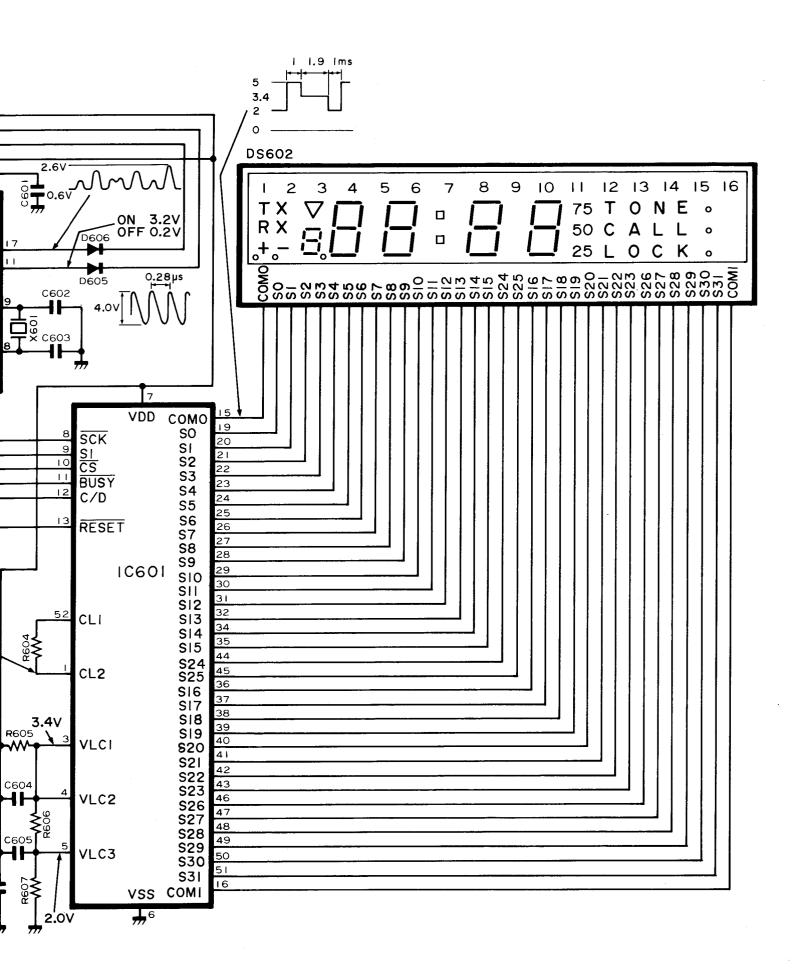


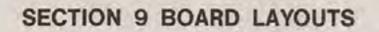




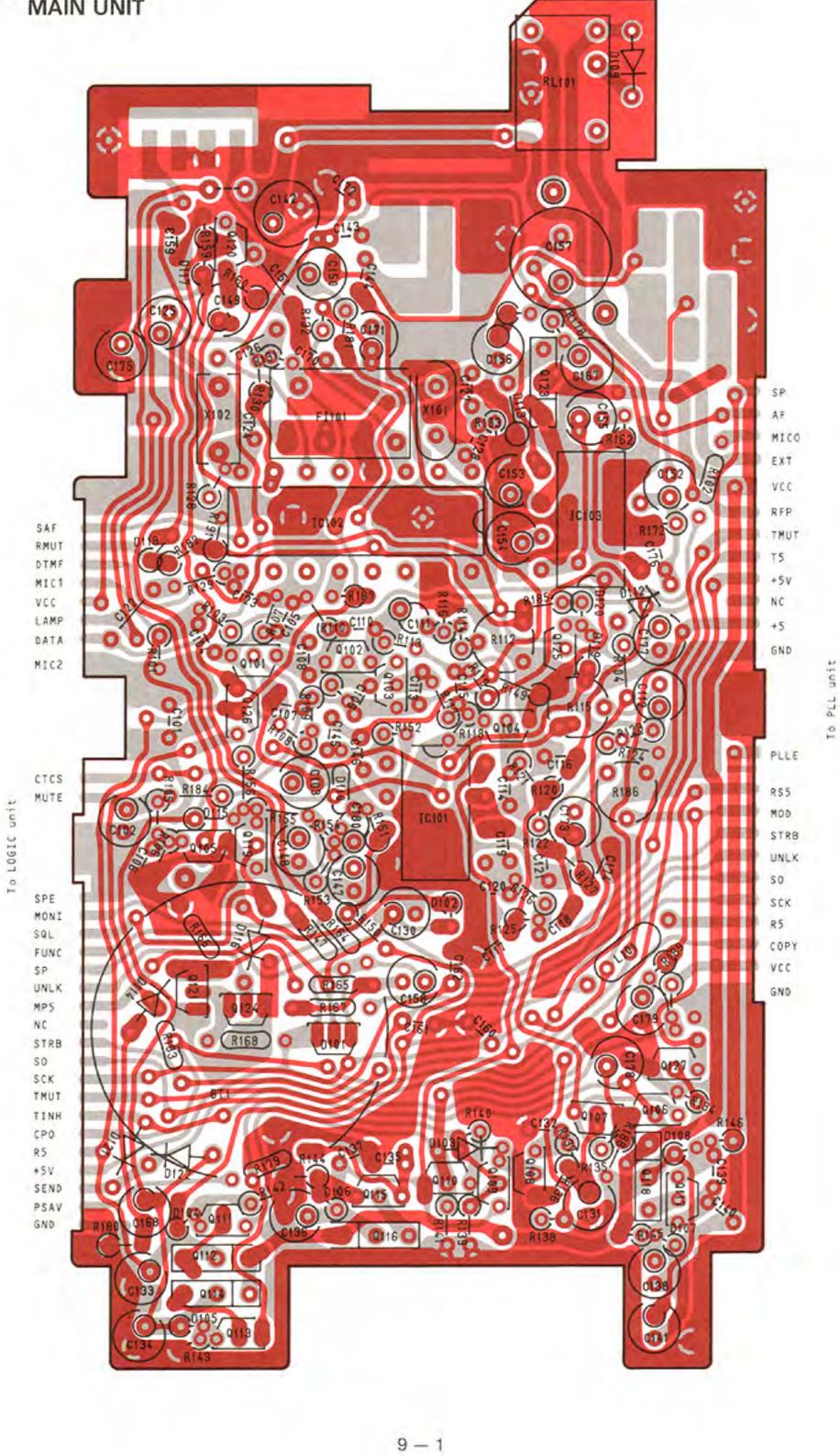




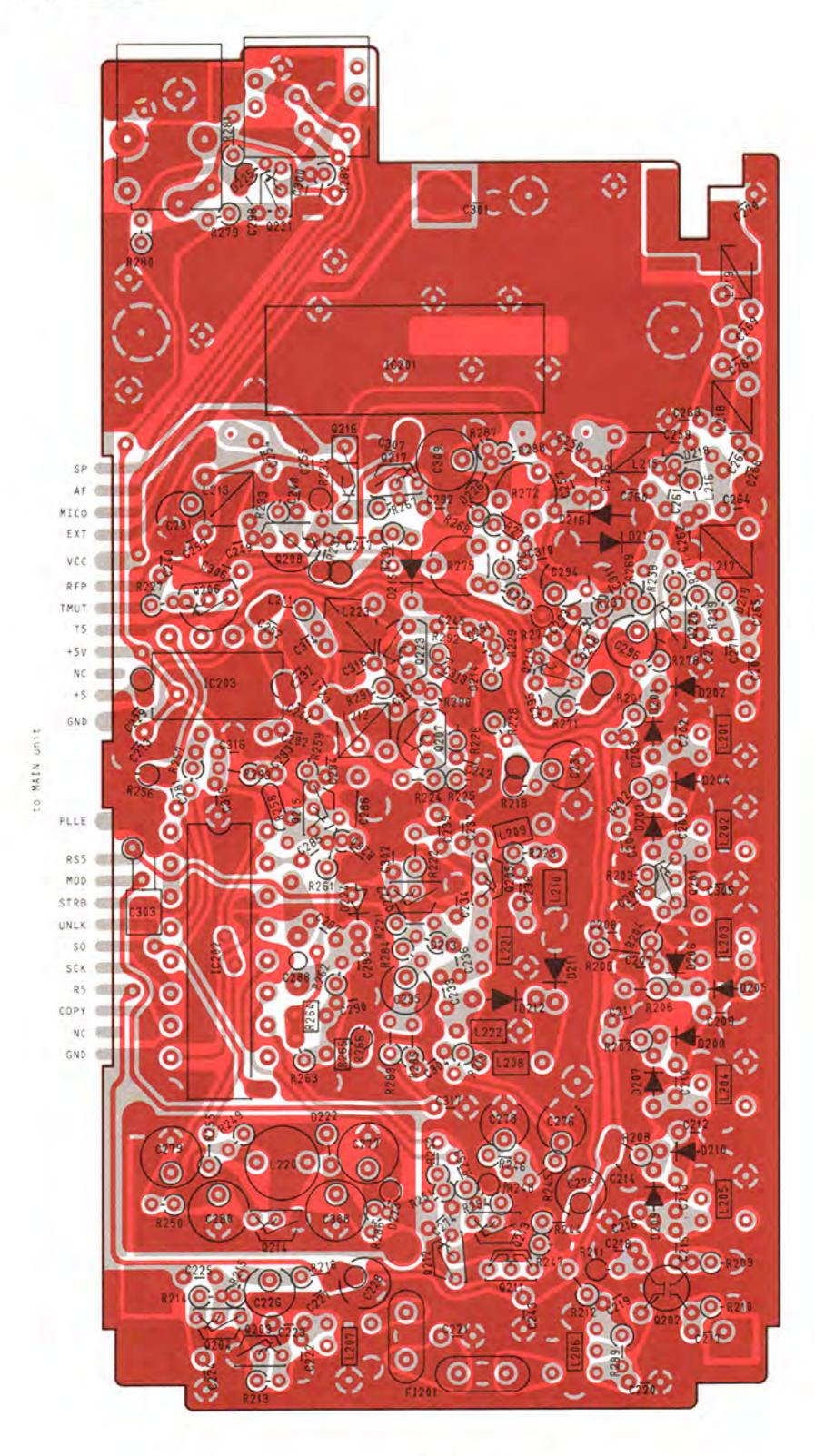




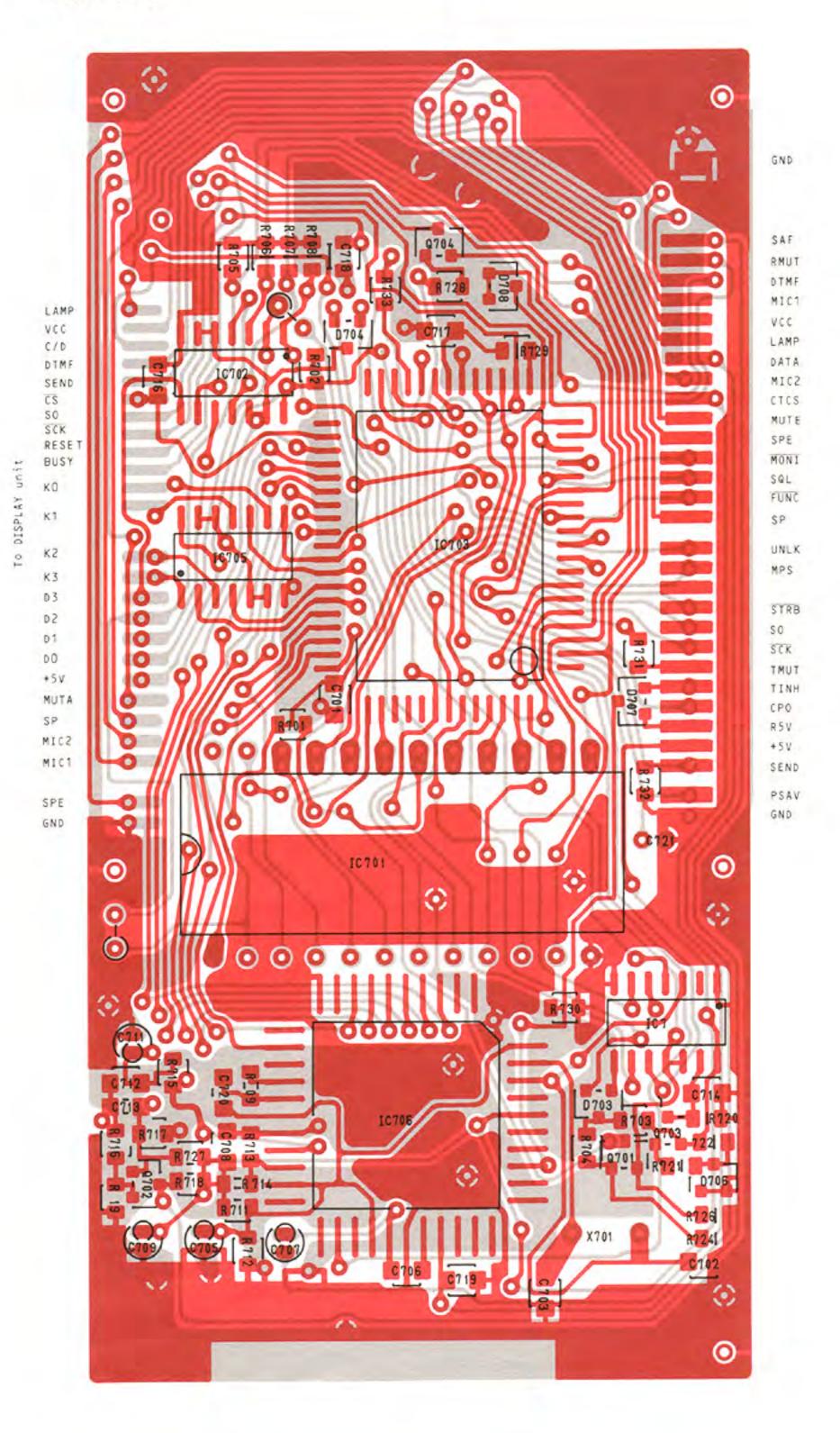
9-1 MAIN UNIT



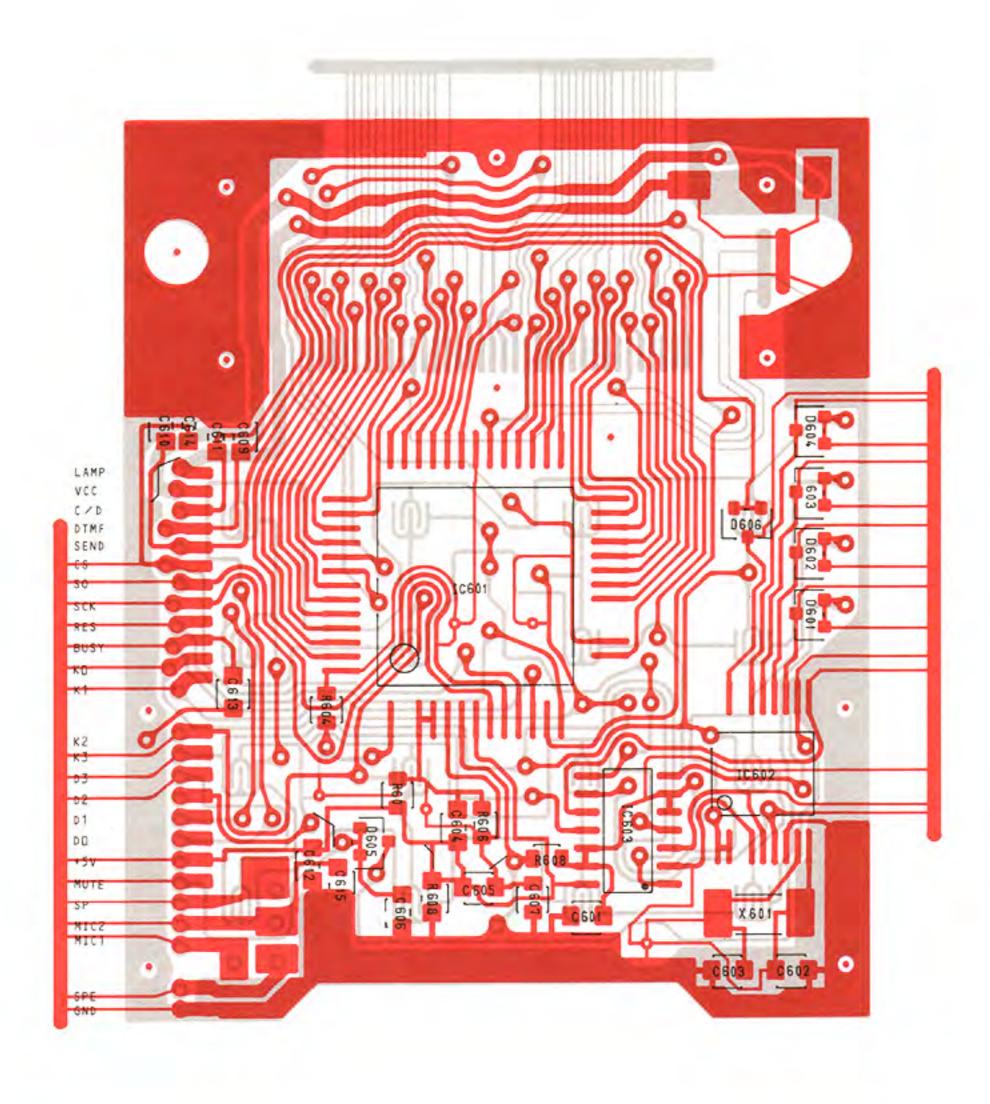
9-2 PLL UNIT



LOGIC UNIT



9 - 4 DISPLAY UNIT



SECTION 10 PARTS LIST

MAIN UNIT

REF. NO.	DESCRIPTION	TYPE (PART NO.)	REF. NO.	DESCRIPTION		PART NO.)	
IC101	IC	μPC358C	L101	CHOKE	LAL03N	A 100K	
IC102	IC	MC3357P	D101	DECISTOR	225	ELR10	
IC103	IC	LM386N-3	R101	RESISTOR	33K		
10000	mathing	1202000122	R102	RESISTOR	1K	B10	
Q101	TRANSISTOR	2SC2458 GR	R103	RESISTOR	1K	ELR10	
0102	TRANSISTOR	2SC2458 GR	R104	RESISTOR	1.2K	ELR10	
Q103	TRANSISTOR	2SA1048 GR	R105	RESISTOR	150K	ELR10	
0104	TRANSISTOR	2SC2458 GR	R106	RESISTOR	100K	ELR10	
Q105	TRANSISTOR	2SC2458 GR	R107	RESISTOR	120K	ELR10	
Q106	TRANSISTOR	2SA1048 GR	R108	RESISTOR	120K	ELR10	
Q107	TRANSISTOR	2SA1048 GR	R109	RESISTOR	470	ELR10	
Q108	TRANSISTOR	2SC2458 GR	R110	RESISTOR	12K	ELR10	
Q109	TRANSISTOR	2SA1048 GR	B111	RESISTOR	5.6K	ELR10	
Q110	TRANSISTOR	2SA1048 GR	R112	TRIMMER	33K	RHMOAN40	5A
Q111	TRANSISTOR	2SC2458 GR	R113	RESISTOR	330K	ELR10	
Q112	TRANSISTOR	2SB909M R	R114	RESISTOR	22K	ELR10	
		2SC2458 GR	R115	TRIMMER	100K	RHM0A1505	A
Q113	TRANSISTOR	CONTRACTOR OF THE CONTRACTOR		RESISTOR	470	ELR10	4.4
0114	TRANSISTOR	2SB909M R	R116				
Q115	TRANSISTOR	2SC2458 GR	R117	RESISTOR	2.2K	ELR10	
Q116	TRANSISTOR	2SB909M R	R118	RESISTOR	1K	ELR10	
0117	TRANSISTOR	2SC2458 GR	R119	RESISTOR	3.3K	ELR10	
Q118	TRANSISTOR	2SB909M R	R120	RESISTOR	150K	ELR10	
Q119	TRANSISTOR	2SC3399 K	R121	RESISTOR	220K	ELR10	
Q120	TRANSISTOR	2SJ105 Y	R122	RESISTOR	39K	ELR10	
Q121	TRANSISTOR	2SC2458 GR	R123	RESISTOR	10K	ELR10	
0123	TRANSISTOR	2SD1225M R	R124	RESISTOR	33K	ELR10	
Q124	TRANSISTOR	2SC2458 GR	R125	RESISTOR	33K	ELR10	
Q125	TRANSISTOR	2SC2458 GR	R126	RESISTOR	39K	ELR10	
Q126	TRANSISTOR	2SC2458 GR	R127	RESISTOR	12K	ELR10	
Q127	FET	2SJ105 Y	R128	RESISTOR	1.5K	ELR10	
0127	FEI	2551051	R129	RESISTOR	470	ELR10	
D.104	DIODE	100000				ELR10	
D101	DIODE	1SS233	R130	RESISTOR	47K	and the second se	i u
D102	DIODE	1SS211	R131	RESISTOR	1.5K	ELR10 (#0	
D103	DIODE	1SS211	4.50	RESISTOR	2.2K	ELR10 (#0	
D104	DIODE	1SS211	R132	RESISTOR	1.5K	ELR10 (#0	
D105	DIODE	1SS211		RESISTOR	2.2K	ELR10 (#0	3)
D106	DIODE	1SS211	R133	RESISTOR	22K	ELR10	
D107	ZENER	RD5.1JS B2	R134	RESISTOR	47K	ELR10	
D108	DIODE	1SS211	R135	RESISTOR	10K	ELR10	
D109	DIODE	1SS211	R136	RESISTOR	100K	ELR10	
D110	DIODE	1SS211	R137	RESISTOR	220K	ELR10	
D112	DIODE	1SS211	R138	RESISTOR	33K	ELR10	
D113	ZENER	RD12JS B2	R139	RESISTOR	10K	ELR10	
D114	DIODE	1SS211	R140	RESISTOR	180K	ELR10	
	DIODE	1SS211	R141	RESISTOR	10K	ELR10	
D115			R141	RESISTOR	10K	ELR10	
D116	DIODE	1SS211					
D117	DIODE	1SS211	R143	RESISTOR	10K	ELR10	
D118	DIODE	1SS211	R144	RESISTOR	10K	ELR10	
D119	DIODE	155211	R145	RESISTOR	6.8K	ELR10	
D120	DIODE	155211	R146	RESISTOR	10K	ELR10	
D121	DIODE	1SS211	R147	RESISTOR	100K	R10	
D122	DIODE	1SS211	R148	VARIABLE	RK9A10	DONA 10K	В
			R149	RESISTOR	5.6K	ELR10	
FI101	CERAMIC FILTER	CFW455 E (#01, #02)	R150	RESISTOR	330K	ELR10	
	CERAMIC FILTER	CFW455 HT (#03)	R151	RESISTOR	180K	ELR10	
	and a second rever	C. Charles M. S. S. W.	R152	RESISTOR	1M	ELR10	
X101	CRYSTAL	CR-70	R153	RESISTOR	100K	ELR10	
X102	DISCRIMINATOR	CDB455 C7A	R154	RESISTOR	1K	ELR10	
1106	biooninina ion	Sector stra	R155	RESISTOR	150K	ELR10	
			PE 100				

MAIN UNIT

MAIN UNIT

MAIN UNIT

REF. NO.	DESCRIPTION	TYPE (PA	ART NO	.)	REF. NO.	DESCRIPTION	TYPE (P	ART NO).)
R156	RESISTOR	680K	ELR10		C139	CERAMIC	470P	50V	
R159	RESISTOR	470K	ELR10		C140	CERAMIC	0.001	50V	
		1M	ELR10		C141	ELECTROLYTIC	22	6.3V	RC3
R160	RESISTOR			10KA	C142	ELECTROLYTIC	47	25V	MS7
R161	VARIABLE	RK9A1100					0.001	20V	14107
R162	RESISTOR	1.8K	ELR10	(#01, #02)	C143	CERAMIC		50V 50V	
	RESISTOR	2.2K	ELR10	(#03)	C144	CERAMIC	0.001		
R164	RESISTOR	100K	R10		C145	CERAMIC	10P	50V	
R165	RESISTOR	33K	R10		C146	CERAMIC	0.001	50V	
R166	RESISTOR	39K	R10		C147	ELECTROLYTIC	0.22	50V	RC3
R167	RESISTOR	120K	R10		C148	ELECTROLYTIC	0.22	50V	RC3
R168	RESISTOR	470K	R10		C149	ELECTROLYTIC	1	50V	RC3
R172	RESISTOR	150K	ELR10		C150	ELECTROLYTIC	1	50V	RC3
R178	RESISTOR	220	ELR10		C151	BARRIER LAY	0.018	25V	
R179	RESISTOR	1K	R10		C152	ELECTROLYTIC	0.1	50V	MS5
R180	RESISTOR	220K	ELR10		C153	ELECTROLYTIC	10	16V	MS5
R181	RESISTOR	27K	ELR10	(#01, #02)	C154	ELECTROLYTIC	10	16V	MS5
NIO1	RESISTOR	68K	ELR10	(#03)	C155	ELECTROLYTIC	10	16V	RC3
R182	RESISTOR	220K	ELR10	(# 00)	C156	ELECTROLYTIC	2.2	50V	RC3
	RESISTOR	47K	R10		C157	ELECTROLYTIC	220	10V	
R183					C158	ELECTROLYTIC	4.7	25V	RC3
R184	RESISTOR	100K	ELR10		C158	CERAMIC	470P	50V	1100
R185	RESISTOR	33K	ELR10	4001/				50V 50V	
R186	TRIMMER	RHM0A15		100K	C160	CERAMIC	47P		
R187	RESISTOR	100K	ELR10		C161	CERAMIC	47P	50V	
R188	RESISTOR	470	ELR10		C162	CERAMIC	47P	50V	
R189	RESISTOR	10	ELR10		C163	CERAMIC	0.001	50V	
R191	RESISTOR	150K	ELR10		C164	CERAMIC	0.001	50V	
					C167	ELECTROLYTIC	4.7	25V	RC3
C101	CERAMIC	0.001	50V		C168	ELECTROLYTIC	1	50V	RC3
C102	ELECTROLYTIC	10	16V	RC3	C170	BARRIER LAY	0.01	25V	
C103	ELECTROLYTIC	10	16V	RC3	C171	ELECTROLYTIC	10	16V	RC3
C104	BARRIER LAY	0.01	25V		C172	CERAMIC	47P	50V	
C105	CERAMIC	470P	50V		C173	ELECTROLYTIC	1	50V	RC3
C106	CERAMIC	470P	50V		C174	MYLAR	0.0022	50V	
C107	CERAMIC	470P	50V		C175	ELECTROLYTIC	0.1	50V	RC3
C108	CERAMIC	470P	50V		C176	CERAMIC	470P	50V	
C109	CERAMIC	470P	50V		C177	ELECTROLYTIC	2.2	50V	RC3
C103	CERAMIC	470P	50V		C178	ELECTROLYTIC	10	16V	RC3
C110 C111	TANTALUM	DN1V0R1	301		C179	ELECTROLYTIC	2.2	50V	RC3
C112	ELECTROLYTIC	0.22	50V	RC3	C180	TANTALUM	DN1V	R47M	
		470P	50V	1105	0100		Ditti	1147111	
C113	CERAMIC		50V		RL101	RELAY	OUC-SS-	114D	
C114	CERAMIC	470P	50V 50V		ILL IUI		000-00-		
C115	CERAMIC	0.001			C101	SWITCH	SKHHAB	1624	
C116	CERAMIC	0.001	50V		S101				
C117	MYLAR	0.0022	50V		S103	SWITCH	SKHHAB		
C118	MYLAR	0.01	50V		S104	SWITCH	-		
C119	CERAMIC	470P	50V		S105	SWITCH	SPPH220		
C120	CERAMIC	120P	50V		S106	SWITCH	SPPH220	14A	
C121	CERAMIC	470P	50V						
C122	MYLAR	0.056	50V		BT101	LITHIUM CELL	BR2325-1	HC	
C123	CERAMIC	0.001	50V				-		
C124	CERAMIC	82P	50V		EP101	P.C.B.	B-1038D		
C125	ELECTROLYTIC	0.1	50V	RC3	EP102	P.C.B.	B-908		
C126	BARRIER LAY	0.1	16V		EP103	F.C.B.	B-1045		
C127	CERAMIC	68P	50V		EP104	BEADS CORE	DL2-0P2.	6-3-1.2H	
C128	CERAMIC	120P	50V		EP106	FILTER SEAT	41590		
C130	ELECTROLYTIC	47	6.3V	RC3	EP107	INSULATING SEAT	-(J)		
C131	ELECTROLYTIC	2.2	50V	RC3					
C132	CERAMIC	0.001	50V						
C133	ELECTROLYTIC	22	6.3V	RC3					
C134	ELECTROLYTIC	22	6.3V	RC3					
C135	CERAMIC	470P	50V	-					
C135	ELECTROLYTIC	22	6.3V	RC3					
C130	CERAMIC	0.001	50V						
C137	ELECTROL	22	6.3V	RC3					
5100				··					

PLL UNIT

REF. NO.	DESCRIPTION	TYPE (PART NO.)	REF. NO.	DESCRIPTION
IC201	IC	SC-1046 (#01, #03)	L207	COIL
	IC	SC-1050 (#02)	L208	CHOKE
IC202	IC	μPD2834C	L209	CHOKE
IC203	IC	MB504	L210	CHOKE
10200	10		L211	CHOKE
Q201	FET	2SK241 GR	L212	COIL
Q202	FET	3SK74 M	L213	COIL
Q202	TRANSISTOR	2SC2668 0	L215	COIL
Q203	TRANSISTOR	2SC2668 0	L216	CHOKE
Q204	FET	2SK192A Y	L210	CHOKE
Q205		2SR152A (L217	CHOKE
	TRANSISTOR	2SC2026	L218 L219	CHOKE
Q207	TRANSISTOR		L219 L220	CHOKE
Q208	TRANSISTOR	2SC2026	L220 L221	COIL
Q211	FET	2SK184 Y	L221	CHOKE
Q212	TRANSISTOR	2SA1048 GR		COIL
0213	TRANSISTOR	2SC2458 GR	L223	COIL
Q214	TRANSISTOR	2SC3327 B	Dood	DECICTOR
Q215	TRANSISTOR	2SC2458 GR	R201	RESISTOR
Q216	TRANSISTOR	2SB909 M	R202	RESISTOR
Q217	TRANSISTOR	2SC2458 GR	R203	RESISTOR
Q218	TRANSISTOR	2SA1048 GR	R204	RESISTOR
Q219	TRANSISTOR	2SA1048 GR	R205	RESISTOR
Q220	TRANSISTOR	2SC2458 GR	R206	RESISTOR
0221	TRANSISTOR	2SA1048 GR	R207	RESISTOR
0222	TRANSISTOR	2SC3399	R208	RESISTOR
Q223	TRANSISTOR	2SC2026	R209	RESISTOR
_			R210	RESISTOR
D201	VARICAP	1SV153	R211	RESISTOR
D202	VARICAP	1SV153	R212	RESISTOR
D203	VARICAP	1SV153	R213	RESISTOR
D204	VARICAP	1SV153	R214	RESISTOR
D205	VARICAP	1SV153	R215	RESISTOR
D206	VARICAP	1SV153	R216	RESISTOR
D207	VARICAP	1SV153	R218	RESISTOR
D208	VARICAP	1SV153	R219	RESISTOR
D209	VARICAP	1SV153	R221	RESISTOR
D210	VARICAP	1SV153	R222	RESISTOR
D211	VARICAP	1SV50E	R223	RESISTOR
D212	VARICAP	1SV50E	R224	RESISTOR
D213	DIODE	1SS216	R225	RESISTOR
D214	DIODE	1SS216	R226	RESISTOR
D215	DIODE	1SS216	R227	RESISTOR
D216	DIODE	1SS97	R228	RESISTOR
D217	DIODE	1SS97	R229 R230	RESISTOR RESISTOR
D218	DIODE	1SS216	R230	
D219	DIODE	1SS216	R231	RESISTOR
D222	DIODE	1SS130	R232 R233	RESISTOR
D223	ZENER VARICAP	RD18J B2 1SV50E	R233	RESISTOR RESISTOR
D224			R237	RESISTOR
D225 D226		1SS211 RD5.1JS B2	R239	RESISTOR
D220	ZENER	RD5. 135 B2	R239 R244	RESISTOR
FI201	MC	21M15B3 (#01, #02)	R244	RESISTOR
FIZUT	MC	21M7B2 (#03)	R246	RESISTOR
	IVIC	21101762 (#03)	R240	RESISTOR
X201	CRYSTAL	CR-164 (#01, #02)	R248	RESISTOR
7201	CRYSTAL	CR-85 (#03)	R249	RESISTOR
	CITIOTAL		R250	RESISTOR
L201	COIL	LS-295	R250	RESISTOR
L201	COIL	LS-295	R251	RESISTOR
L202	COIL	LS-296	R252	RESISTOR
L203	COIL	LS-295	R254	RESISTOR
L205	COIL	LS-295	R255	RESISTOR
L206	COIL	LS-264	R256	RESISTOR

PLL UNIT

TYPE (PART NO.)

4R7

ELR10

ELR10 ELR10

ELR10 ELR10

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ELR10

ELR10

ELR10

ELR10 ELR10

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ELR10 ELR10

LS-264 LAL02TA 4R7 LAL02TA 4R7 LAL02TA 4R7 LAL03NA 221 LA-237 LA-237 LA-235 LAL03A

LA-237 LA-235 LA-234 LW-30 LB-188 LAL02TA 4R7 LA-237

150K

150K

18 6.8K

100 150K

150K

150K

220K

47K

18

68 22K

22K

3.3K

100

100

2.2K

8.2K

22K

100

5.6K 4.7K

470

6.8K

10K

22K

10K

1.2K

560

47

4.7K

4.7K

330

10K

22K

2.7K

120K

1K

10K

330

10K

100K

100K

33K

10K

1K

PLL UNIT

PLL UN	IT				PLLUN				
REF. NO.	DESCRIPTION	TYPE (F	PART NO.)	REF. NO.	DESCRIPTION	TYPE (P	PART NO	.)
R257	RESISTOR	10K	ELR10		C223	CERAMIC	4P	50V	
R258	RESISTOR	120K	R10		C224	BARRIER LAY	0.0047	25V	
R259	RESISTOR	2.2K	ELR10		C225	CERAMIC	0.001	50V	
R260	RESISTOR	68K	ELR10		C226	ELECTROLYTIC	1	50V	RC
R261	RESISTOR	6.8K	ELR10		C227	BARRIER LAY	0.0047	25V	
R262	RESISTOR	10K	ELR10		C228 ·	ELECTROLYTIC	10	16V	RC
R263	RESISTOR	10K	ELR10		C229	CERAMIC	0.001	50V	
R264	THERMISTOR	33D28			C231	ELECTROLYTIC	47	6.3V	RC
R265	THERMISTOR	33D28			C232	CERAMIC	10P	50V	
R266	RESISTOR	15K	ELR10		C233	CERAMIC	470P	50V	
R267	RESISTOR	15K	ELR10		C234	CERAMIC	0.001	50V	
R268	RESISTOR	560K	ELR10		C235	ELECTROLYTIC	10	16V	RC
R269	RESISTOR	22K	ELR10		C236	CERAMIC	5P	50V	
R270	RESISTOR	220K	ELR10		C237	CERAMIC	0.001	50V	
R271	RESISTOR	82K	ELR10		C238	CERAMIC	0.001	50V	
R272	TRIMMER	RHM0AJ		22K	C239	CERAMIC	1P	50V	
R273	RESISTOR	2.2K	ELR10		C240	CERAMIC	0.001	50V	
R274	RESISTOR	22K	ELR10		C241	CERAMIC	0.001	50V	
R275	TRIMMER	RHM0AJ		2.2K	C242	CERAMIC	0.001	50V	
R276	RESISTOR	8.2K	ELR10		C243	CERAMIC	470P	50V	
R277	RESISTOR	47K	ELR10		C244	CERAMIC	10P	50V	
R278	RESISTOR	1M	ELR10		C245	CERAMIC	22P	50V	
R279	RESISTOR	27	ELR10		C247	CERAMIC	4P	50V	
R280	RESISTOR	5.6K	ELR10		C248	CERAMIC	0.001	50V	
R281	RESISTOR	47K	ELR10		C249	CERAMIC	10P	50V	
R282	RESISTOR	47K	ELR10		C251	CERAMIC	4P	50V	
R283	RESISTOR	10K	ELR10		C252	CERAMIC	RPE121C		0.
R284	RESISTOR	82K	ELR10		C253	CERAMIC	0.001	50V	
R285	RESISTOR	220K	ELR10		C254	CERAMIC	10P	50V	
R286	RESISTOR	100	ELR10		C255	CERAMIC	0.001	50V	
R287	RESISTOR	6.8K	ELR10		C256	BARRIER LAY	0.75	50V	
R288	RESISTOR	6.8K	ELR10		C257	CERAMIC	2P	50V	
R289	RESISTOR	8.2K	ELR10		C258	CERAMIC	10P	50V	
R290	RESISTOR	4.7K	ELR10		C259	CERAMIC	10P	50V	
R291	RESISTOR	5.6K	ELR10		C260	CERAMIC	2P	50V	
R292	RESISTOR	470	ELR10		C261	BARRIER LAY	0.75 470P	50V 50V	
R293	RESISTOR	100	ELR10		C262	CERAMIC	0.001	50V 50V	
	0554440	0.004	501		C263 C264	CERAMIC CERAMIC	15P	50V 50V	
C201	CERAMIC	0.001	50V		C264	CERAMIC	15P	50V	
C202	CERAMIC	3P	50V		C265 C266	CERAMIC	15P	50V 50V	
C203	CERAMIC	0.001	50V		C260 C267	CERAMIC	2P	50V	
C204	CERAMIC	0.001	50V	(#01 #02)	C267	CERAMIC	27P	50V	
C205	CERAMIC	0.5P 1P	50V 50V	(#01, #03) (#02)	C268 C269	CERAMIC	8P	50V	
0000	CERAMIC	0.001	50V 50V	(#02)	C203	CERAMIC	12P	50V	
C206	CERAMIC	0.001	50V 50V		C270	CERAMIC	120P	50V	
C207 C208	CERAMIC	0.001	50V 50V		C272	CERAMIC	470P	50V	
	CERAMIC	2P	50V 50V		C272	CERAMIC	0.001	50V	
C209	CERAMIC	2F 0.5P	50V 50V	(#01, #03)	C273	CERAMIC	100P	50V	
C210	CERAMIC	0.5F 1P	50V 50V	(#01, #03) (#02)	C274	ELECTROLYTIC	0.1	50V	R
0011	CERAMIC	0.001	50V 50V	(#02)	C275	TANTALUM	DN1V0R		
C211	CERAMIC	2P	50V 50V		C270	ELECTROLYTIC	10	35V	R
C212	CERAMIC CERAMIC	2F 0.5P	50V 50V	(#01, #03)	C278	TANTALUM	DN1V	2R2M	
C213	CERAMIC	0.5r 1P	50V 50V	(#01, #03) (#02)	C279	ELECTROLYTIC	47	6.3V	R
C214	CERAMIC	0.001	50V 50V	(#02)	C280	ELECTROLYTIC	47	6.3V	R
C214 C215	CERAMIC	6P	50V 50V		C281	CERAMIC	0.001	50V	
C215 C216	CERAMIC	6F 1P	50V 50V		C281	CERAMIC	0.001	50V	
C216 C217	CERAMIC	22P	50V 50V		C283	BARRIER LAY	0.001	25V	
C217 C218	CERAMIC	0.001	50V 50V		C284	CERAMIC	100P	50V	
C218 C219	CERAMIC	0.001	50V 50V		C285	CERAMIC	0.001	50V	
C219 C220	CERAMIC	47P	50V 50V		C286	CERAMIC	220P	50V	
	CERAMIC	5P	50V 50V	(#01, #02)	C287	CERAMIC	33P	50V	С
C221		~ 1		(" U I I I U L I					
C221	CERAMIC	15P	50V	(#03)	C288	TRIMMER	ECRGA0	20E30	20

PLL UNIT

RC2

RC2

RC2

RC3

0.1

RC2

RC2

RC2

RC2

СН

20P

СН

PLL UNIT

REF. NO.	DESCRIPTION	TYPE (PA	RT NO	.)
C290	CERAMIC	0.001	50V	
C291	TANTALUM	DN1C	4R7M	
C292	CERAMIC	0.001	50V	
C293	CERAMIC	0.001	50V	
C294	TANTALUM	DN1C	4R7M	
C295	CERAMIC	0.001	50V	
C296	ELECTROLYTIC	10	16V	RC2
C298	CERAMIC	470P	50V	
C300	CERAMIC	470P	50V	
C301	CERAMIC	0.001	50V	
C302	CERAMIC	0.001	50V	
C303	ELECTROLYTIC	2.2	50V	RC2
C304	BARRIER LAY	150P	50V	
C305	CERAMIC	0.5P	50V	
C306	CERAMIC	0.001	50V	
C307	CERAMIC	0.001	50V	
C308	ELECTROLYTIC	10	35V	RC2
C309	ELECTROLYTIC	47	6.3V	RC2
C310	CERAMIC	0.001	50V	
C311	CERAMIC	0.001	50V	
C312	CERAMIC	5P	50V	
C313	CERAMIC	0.001	50V	
C314	CERAMIC	0.001	50V	
C315	CERAMIC	0.001	50V	~ ~
C316	CERAMIC	RPE121C10		0.1
C317	CERAMIC	0.001	50V	
C318	CERAMIC	470P	50V	
J201	CONNECTOR	HSJ-0836-0	01-010	
J202	CONNECTOR	TNC102-N	1-W1-L1	
J203	CONNECTOR	HSJ-1102-0	01-040	
J204	CONNECTOR	HEC-0747-	01-010	
J205	CONNECTOR	171255-1		
J206	CONNECTOR	171255-1		
EP201	P.C.B.	B-1146B		
EP207	FILTER SEAT	41590		
EP212	ALUMINIUM SEAT	42356		
EP213	SHIELDING PLATE	41911		
EP214	F.P.C.	B-1050		
EP215	F.P.C.	B-1044		
EP217	GROUND SPRING	41595		
W205	JUMPER	JPW-02A		
DISPLA	YUNIT			
REF. NO.	DESCRIPTION	TYPE (PA	RT NO	.)
IC601	IC	μPD7225G		
IC601	IC	LR40872		
IC602	IC	μPD4066B	G	
		•	-	
D601	DIODE	1SS190		
D602	DIODE	1SS190		

DIODE

DIODE

DIODE

DIODE

CERALOCK

D603 D604

D605

D606

X601

1SS190

1SS190

1SS190

1SS190

CSAC3.58MG

REF. NO. DESCRIPTION **TYPE (PART NO.)** CHIP 180K MCR10 R604 CHIP 15K MCR10 R605 CHIP 15K MCR10 R606 CHIP 22K MCR10 R607 R608 CHIP 47K MCR10 C601 MONOLITHIC 0.001 GRM40 C602 MONOLITHIC 30P GRM40 C603 MONOLITHIC 30P GRM40 C604 MONOLITHIC 0.001 GRM40 C605 MONOLITHIC 0.001 GRM40 C606 MONOLITHIC 0.001 GRM40 C607 CERAMIC 470P 50V GRM40 C608 MONOLITHIC 0.001 GRM40 C609 MONOLITHIC 0.001 GRM40 C610 MONOLITHIC 0.001 47P GRM40 C611 MONOLITHIC GRM40 MONOLITHIC 0.001 C612 GRM40 MONOLITHIC 47P C613 GRM40 47P MONOLITHIC C614 GRM40 470P C615 MONOLITHIC DS601 LAMP BQ031-22403A DS602 LP217A-E LCD P.C.B. B-1049C EP603 EP604 F.P.C. B-1046A

LOGIC UNIT

DISPLAY UNIT

REF. NO.	DESCRIPTION	TYPE (I	PART NO.)
IC701	IC	μPD4460	2
IC702	IC	μPD4066	6BG
IC703	IC	μPD78C	06A
IC704	IC	μPD406	ÐUBG
IC705	IC	μPD406	6BG
IC706	IC	MN6520	
Q701	TRANSISTOR	2SC2712	2 Y
Q702	TRANSISTOR	2SC2712	2 Y
Q703	TRANSISTOR	2SA1162	2 Y
Q704	TRANSISTOR	2SA1162	2 Y
D703	DIODE	1SS181	
D704	DIODE	1SS181	
D706	ZENER	RD5.1M	B2
D707	DIODE	1SS184	
D708	DIODE	1SS181	
D709	DIODE	1 S 953	
X701	CRYSTAL	RF-4A3F	ACNHD
R701	CHIP	47K	MCR10
R702	CHIP	47K	MCR10
R703	CHIP	47K	MCR10
R704	CHIP	47K	MCR10
R705	CHIP	47K	MCR10
R706	CHIP	47K	MCR10
R707	CHIP	47K	MCR10
R708	CHIP	47K	MCR10
R709	CHIP	820K	MCR10
R711	CHIP	10K	MCR10

LOGIC UNIT

REF. NO.	DESCRIPTION	TYPE (P	PART NO.)
R712	CHIP	10K	MCR10
R713	CHIP	10K	MCR10
R714	CHIP	15K	MCR10
R715	CHIP	10K	MCR10
R716	CHIP	4.7K	MCR10
R717	CHIP	470K	MCR10
R718	CHIP	6.8K	MCR10
R719	CHIP	820	MCR10
R720	CHIP	47K	MCR10
R721	CHIP	68K	MCR10
R722	CHIP	15K	MCR10
R724	CHIP	1M	MCR10
R726	CHIP	100K	MCR10
R727	CHIP	1M	MCR10
R728	CHIP	220K	MCR10
R729	CHIP	470K	MCR10
R730	CHIP	47K	MCR10
R731	CHIP	1K	MCR10
R732	CHIP	47K	MCR10
R733	RESISTOR	0	MCR10
C701	MONOLITHIC	0.1	GRM40 F

LOGIC UNIT

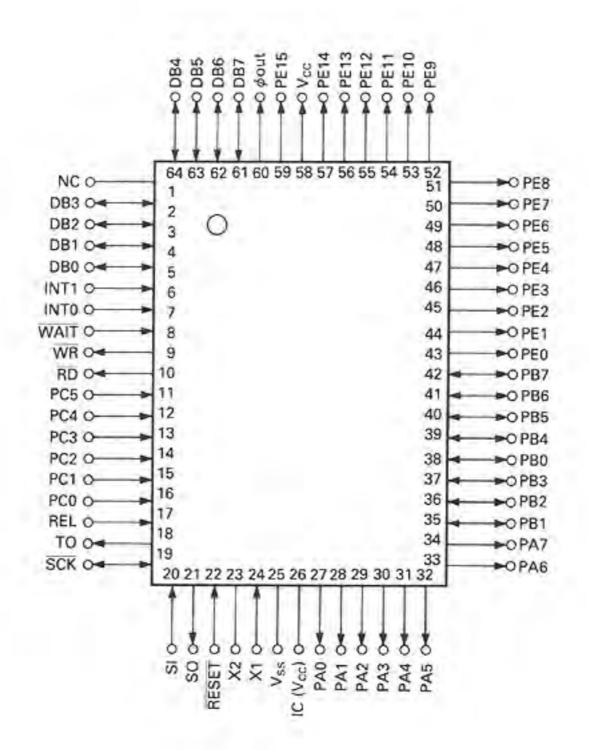
REF. NO.	DESCRIPTION	TYPE (P/	ART NO.)
C702	MONOLITHIC	5P	GRM40
C703	MONOLITHIC	18P	GRM40
C705	ELECTROLYTIC	22	6.3V RC3
C706	MONOLITHIC	0.1	GRM40 F
C707	ELECTROLYTIC	1	50V RC3
C708	MONOLITHIC	0.01	GRM40 F
C709	ELECTROLYTIC	22	16V RC3
C711	ELECTROLYTIC	0.1	50V RC3
C712	MONOLITHIC	0.1	GRM40 F
C713	MONOLITHIC	0.01	GRM40 F
C714	MONOLITHIC	0.01	GRM40 F
C716	MONOLITHIC	47P	GRM40
C717	MONOLITHIC	0.01	GRM40 F
C718	MONOLITHIC	0.001	GRM40
C719	MONOLITHIC	0.01	GRM40 F
C720	MONOLITHIC	0.1	GRM40 F
C722	TANTALUM	3.3	16V
EP702	P.C.B.	B-1048D	
EP703	SHIELDING PLATE	(C)	40639

SECTION 11 IC SPECIFICATIONS

µPD78C06A (MPU)

MAXIMUM RATINGS (Ta = 25°C)

DESCRIPTION	SYMBOL	RATINGS	UNIT
Supply Voltage	Vec	-0.3~7.0	v
Input And Output Voltage	VT	-0.3~Vcc+0.3	v
Output Current (High level)	Іон	-5	mA
Output Current (Low level)	lór,	43.5	mA
Operating Temperature	Торя	-40~85	°C
Storage Temperature	Tstg	-65~150	°C

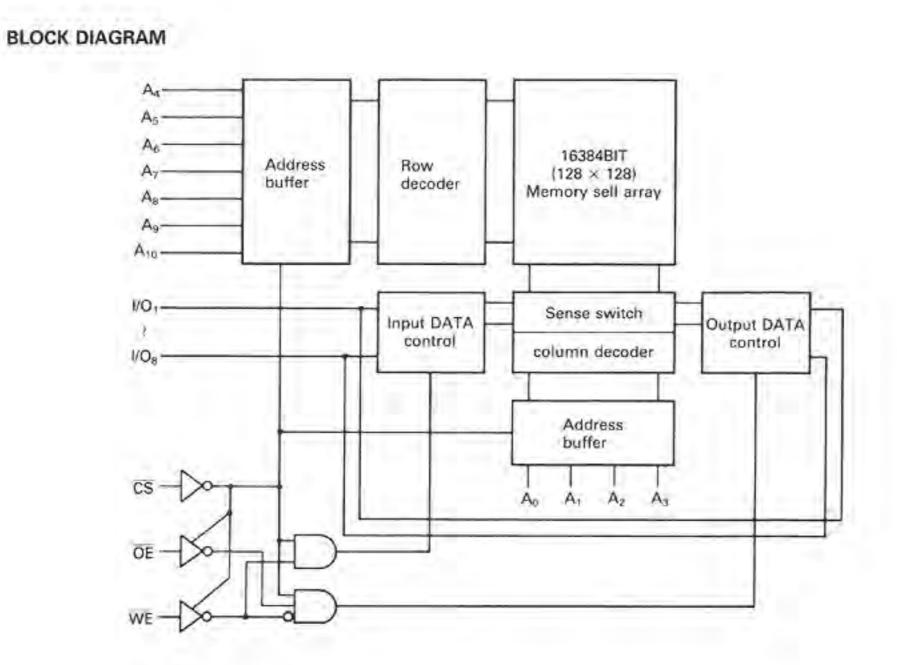


µPD446 (16384 BIT STATIC CMOS RAM)

MAXIMUM RATINGS (Ta = 25°C)

DESCRIPTION	SYMBOL	RATINGS	UNIT
Supply Voltage	Vcc	7.0	v
Input And Output Voltage	Vr	-0.3~Vcc+0.3	v
Operating Temperature	Торя	-40~85	°C
Storage Temperature	Tsig	-55-125	°C

		_	
A ₂	1	24	b Vec
A	2	23	As
A ₅	3	22	D Ag
A.C	4	21	WE
A ₃	5	20	D OE
A ₂	6	19	1 A10
A1 C	7	18	CS
A	8	17	
10,0	9	16	110,
1/Q2	10	15	□ 1/O ₆
1/O3 [11	14	□ 1/Os
GNDE	12	13	□ 1/O4
	-	_	1

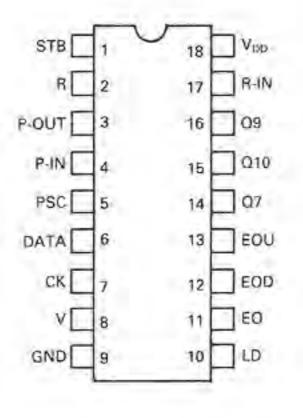


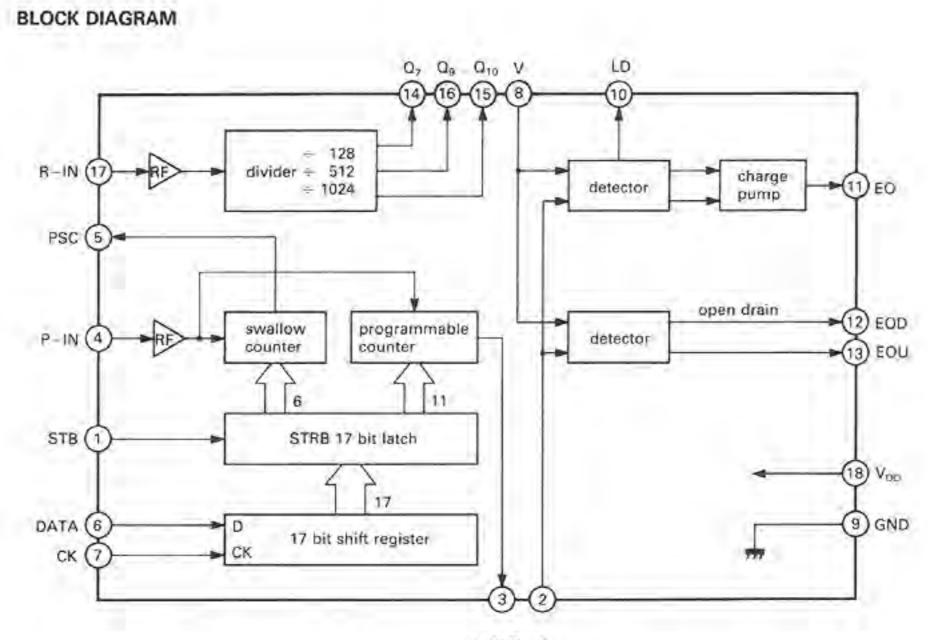
µPD2834C (PLL FREQUENCY SYNTHESIZER)

MAXIMUM RATINGS (Ta = 25°C)

DESCRIPTION	SYMBOL	RATINGS	UNIT	REMARKS
Supply Voltage	Vpp	-0.3~+7.0	v	
Input Voltage	VIN	-0.5~+Vpo+0.5	V	
Output Voltage	Vout	-0.5~+Voo+0.5	v	
Output Voltage	Vout	-0.5~+V _{DD} +3.0	V	EOU pins only
Operating Temperature	TOPR	-40~+85	°C	
Storage Temperature	TSTR	-65~+150	°C	

PIN CONNECTION





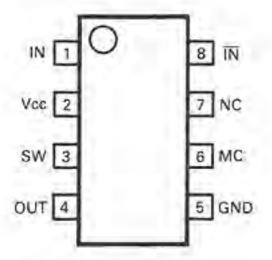
P-OUT R

MB504 (HIGH SPEED PRESCALER)

MAXIMUM RATINGS (ta = 25°C)

DESCRIPTION	SYMBOL	RATINGS	UNIT
Supply Voltage	Vcc	4.5~-5.5	v
Input Voltage	VIN	0.15~2.0	VP.P
Output Current	lo	1.2	mA
Operating Temperature	TOPR	-40~85	°C

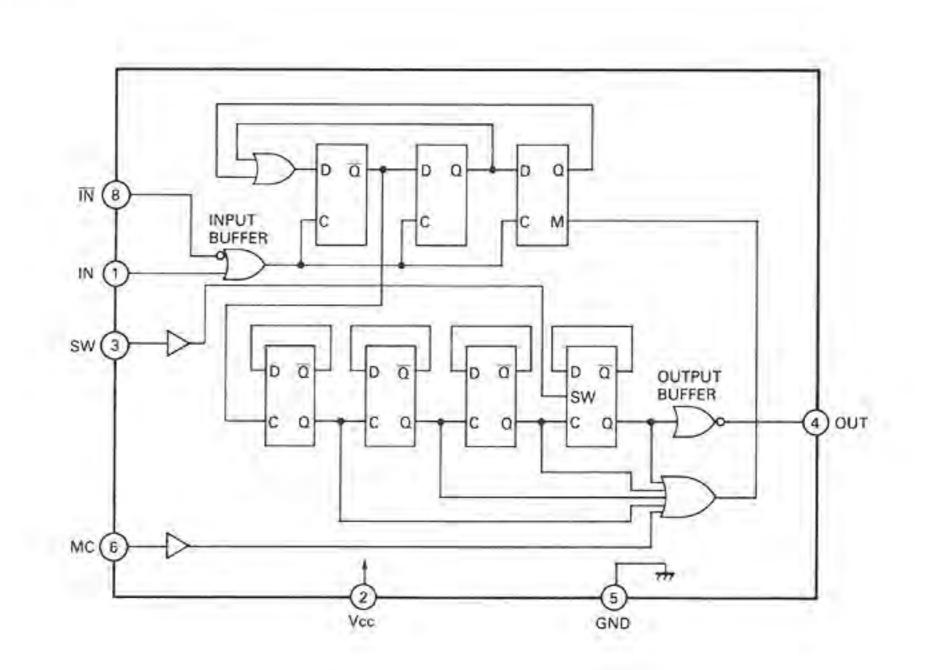
PIN CONNECTION



DIVIDE RATIO

SW	MC	Divide Ratio
н	H	1/32
н	L	1/33
L	н	1/64
L	L	1/65

BLOCK DIAGRAM

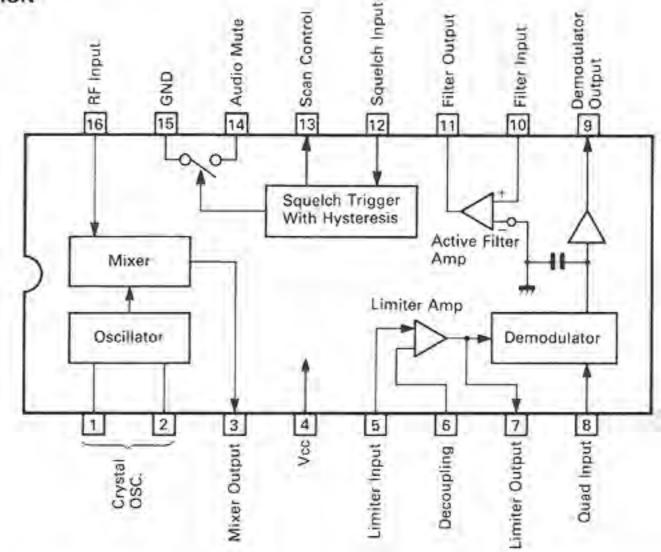


MC3357 (LOW POWER FM IF)

MAXIMUM RATINGS

DESCRIPTION	SYMBOL	RATINGS	UNIT
Power Supply Voltage	Vcc (max)	12	v
Operating Supply Voltage	Vcc	4 or 8	V
Detector Input Voltage		1.0	Vp-p
Input Voltage (Vcc ≥ 6.0 Volts)	V16	1.0	VRMS
Mute Function	V14	-0.5 ~ 5.0	Vpk
Junction Temperature	TJ.	150	°C
Operating Temperature	Torr	-30 ~ 70	°C
Storage Temperature	Tstg	-65 ~ 150	°C

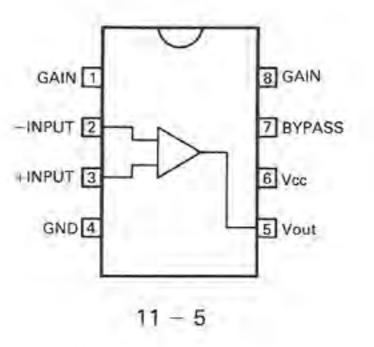
PIN CONNECTION



LM386N-3 (LOW VOLTAGE AUDIO POWER AMPLIFIER)

MAXIMUM RATINGS (Ta = 25°C)

DESCRIPTION	SYMBOL	RATINGS	UNIT
Supply Voltage	Vcc	15	V
Package Dissipation	Po	600	mW
Drive Input Voltage	DVIN	+0.4	v
Operating Temperature	Торя	0 ~ 70	۳C
Stroage Temperature	Tstg	-65 ~ 150	"C

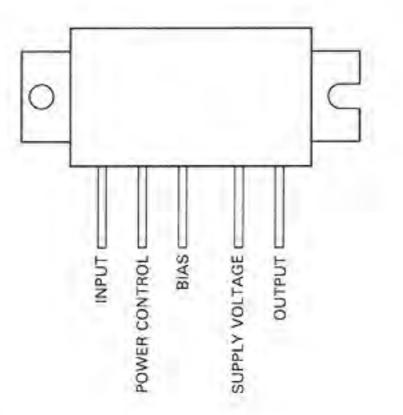


SC-1046, SC-1050 (VHF POWER AMPLIFIER)

MAXIMUM RATINGS

DESCRIPTION	SYMBOL	RATINGS	UNIT
Supply Voltage	Vcc	16	v
Bias Voltage	Veb	6	V
Input Power	Pi	40	mW
Operating Temperature	TOPR	-30~100	°C.
Storage Temperature	Tstg	-40~110	°C.

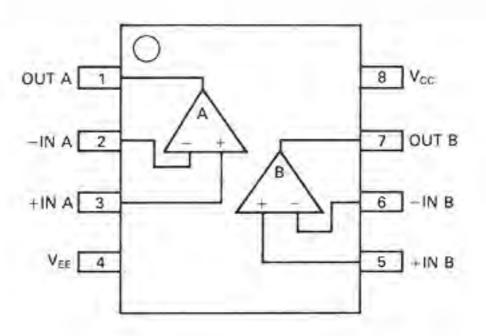
PIN CONNECTION



µPC358C (DUAL DRIVER)

MAXIMUM RATINGS (Ta = 25°C)

DESCRIPTION	SYMBOL	RATINGS	UNIT
Supply Voltage	Vcc	32	v
Drive Input Voltage	DVIN	32	v
Input Voltage	ViN	-0.3~32	V
Permissible Dissipation	Po	350	Wm
Operating Temperature	TOPR	0~70	D°
Storage Temperature	Tstg	-55~125	°C

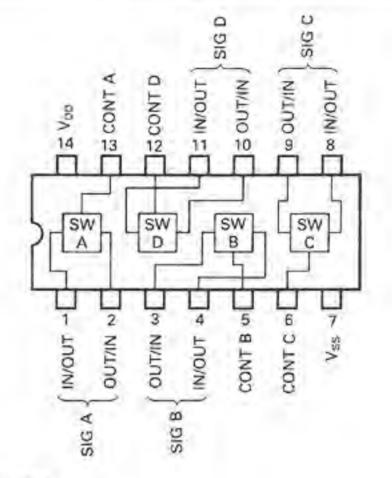


µPD4066BG (QUAD BILATERAL SWITCH)

MAXIMUM RATINGS (Ta = 25°C)

DESCRIPTION	SYMBOL	RATINGS	UNIT
Supply Voltage	Vpd	-0.5~20	v
Input Voltage	Vin	-0.5~Voo+0.5	V
Input Current	Ini	10	mA
Permissible Dissipation	Pò	200	mW
Operating Temperature	TOPR	-40~85	°C
Storage Temperature	Tstg	-65 ~ 125	°C

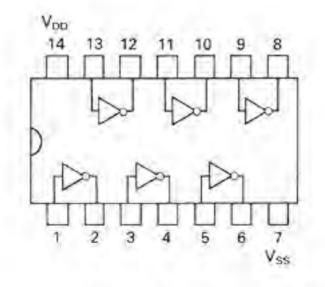
PIN CONNECTION



µPD4069UBG (HEX INVERTER)

MAXIMUM RATINGS

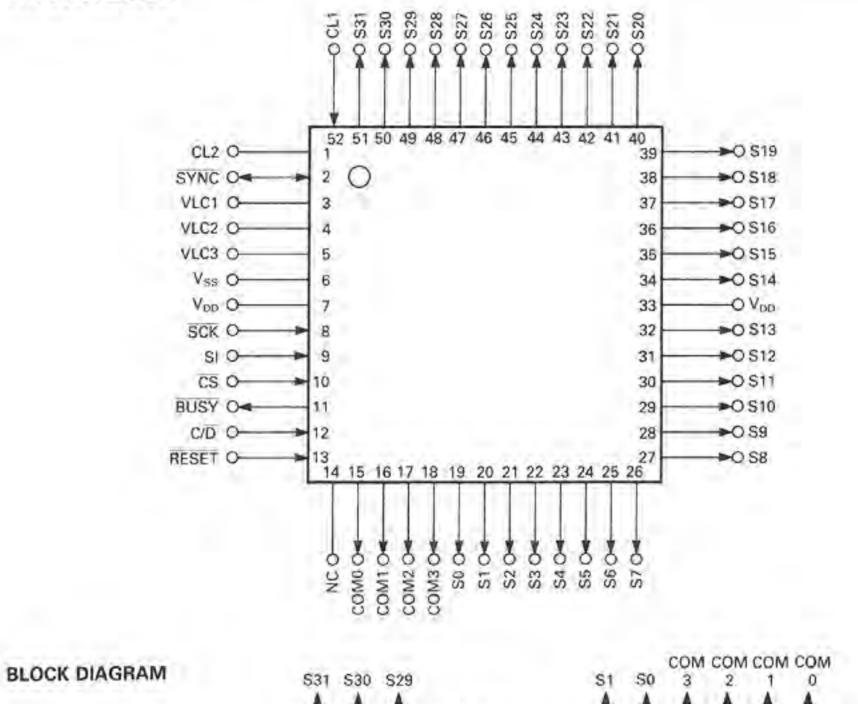
DESCRIPTION	SYMBOL	RATINGS	UNIT
Supply Voltage	Vod	Vss-0.5~Vss+20	v
Input Voltage	Vin	Vss-0.5Vpp+0.5	V
Output Voltage	Vour	Vss-0.5~Voo+0.5	V
Input Current	list	±10	mA
Permissible Dissipation	Po	300	mW
Storage Temperature	Tstg	-65~150	°C

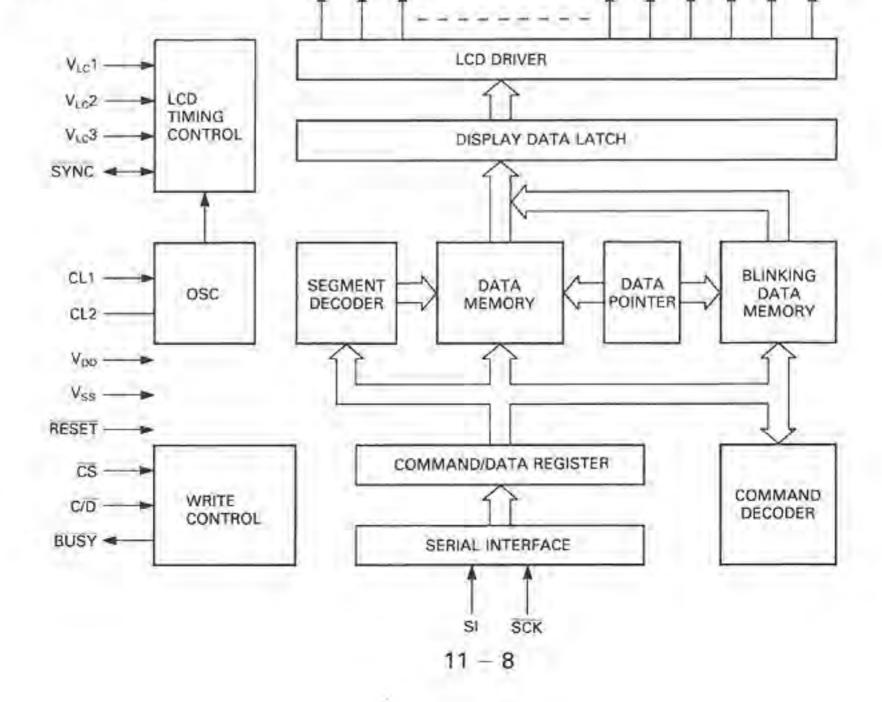


µPD 7225G (PROGRAMMABLE LCD DRIVER)

MAXIMUM RATINGS (Ta = 25°C)

DESCRIPTION	SYMBOL	RATINGS	UNIT
Supply Voltage	Voo	-0.37.0	v
Input Voltage	Vin	-0.3Vpp+0.3	v
Output Voltage	Vour	-0.3~Voo+0.3	v
Operating Temperature	Торя	-1070	°C
Storage Temperature	Tstg	-65~150	°C



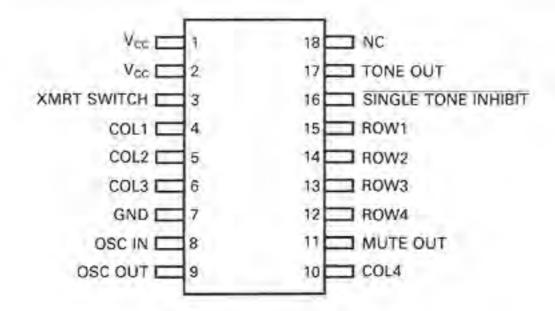


LR40872 (DUAL TONE MULTI FREQUENCY IC)

MAXIMUM RATINGS (Ta = 25°C)

DESCRIPTION	SYMBOL	RATINGS	UNIT
Supply Voltage	Vcc	10.5	v
Input Voltage	Vin	-0.3~Vcc+0.3	v
Power Dissipation	Po	500	mW
Operating Temperature	TOPR	-30~60	°C
Storage Temperature	Tstg	-55 - 150	°C

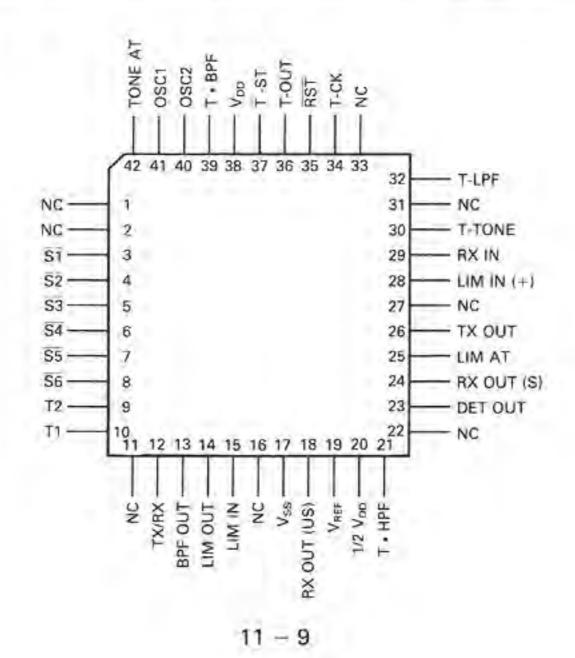
PIN CONNECTION

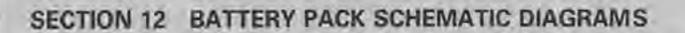


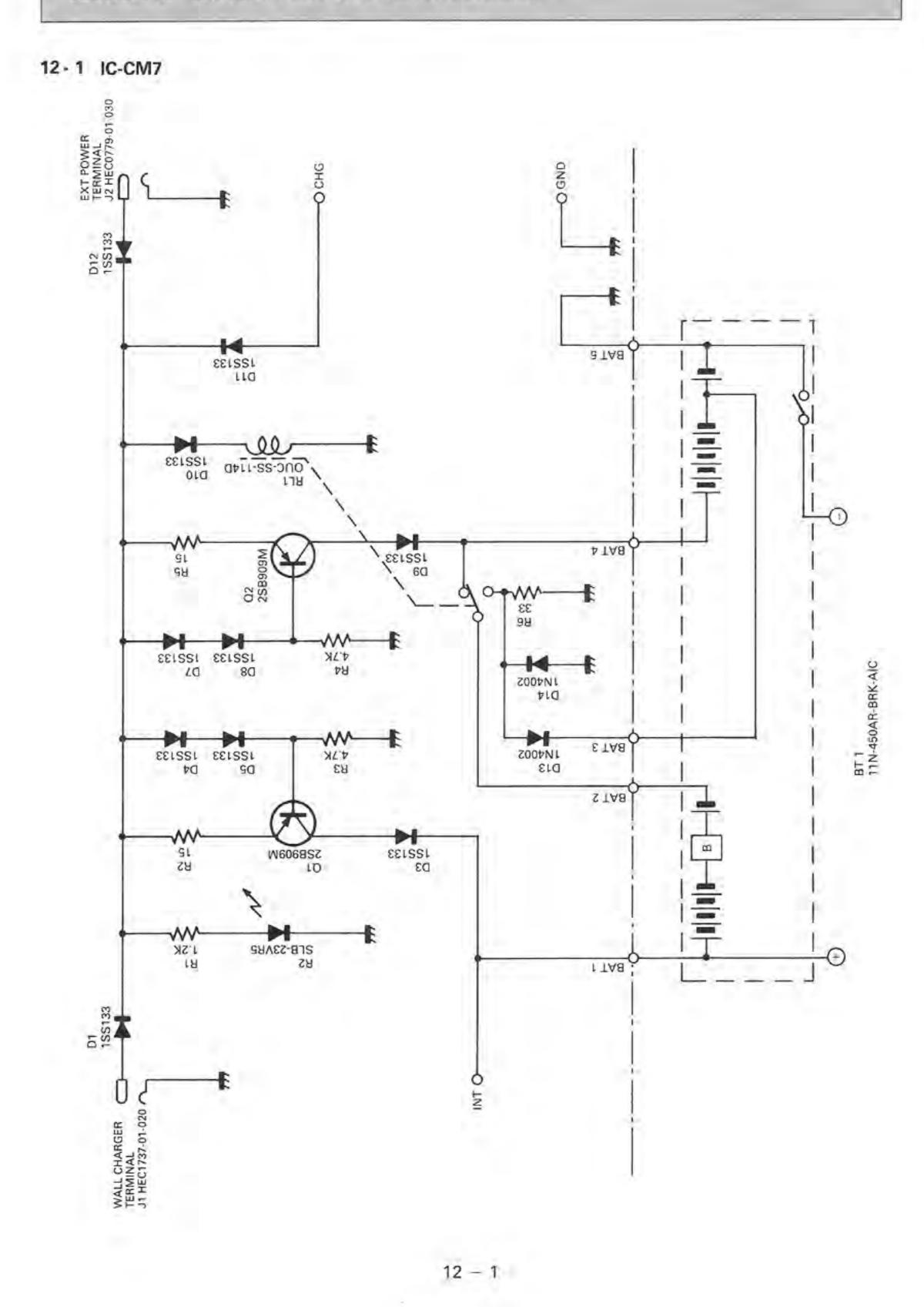
MN6520 (CTCSS ENCODER DECODER)

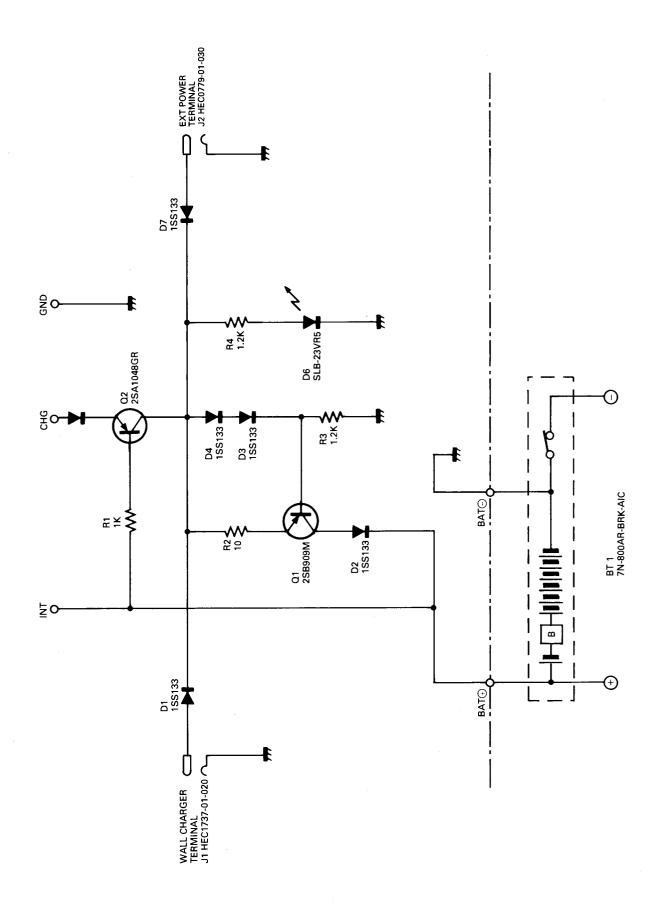
MAXIMUM RATINGS (Ta = 25°C)

DESCRIPTION	SYMBOL	RATINGS	UNIT
Supply Voltage	Vop	-0.2~7.0	v
Input And Output Voltage	Vī	-0.2~Vpp+0.2	v
Power Dissipation	Po	100	wm
Operating Temperature	TOPR	-20~70	°C
Storage Temperature	Тята	-55~100	°C

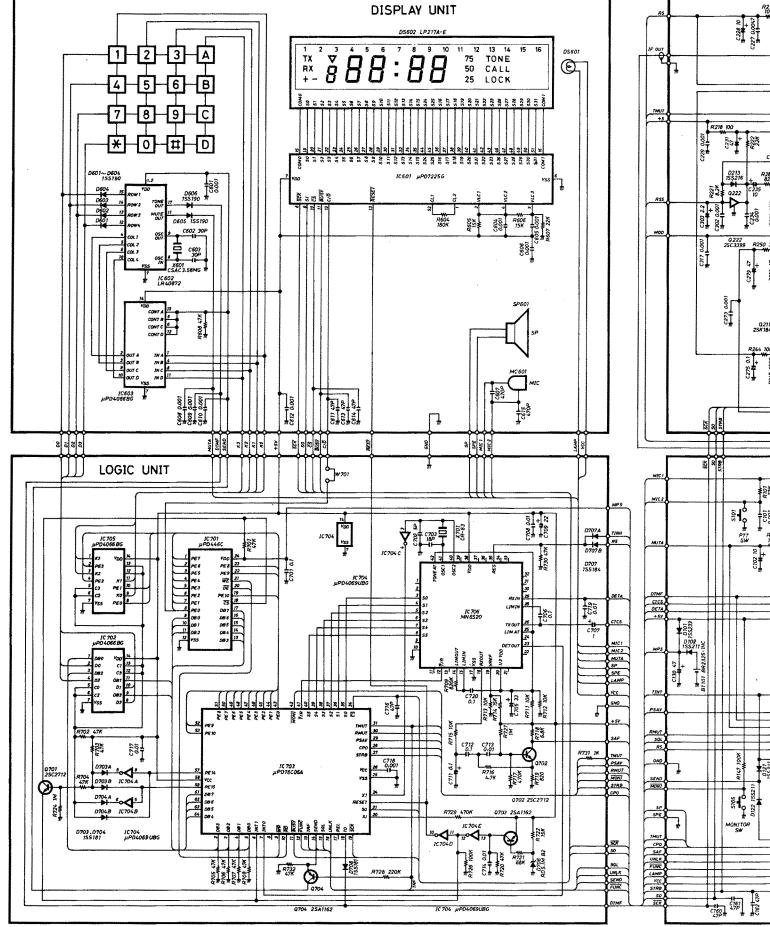




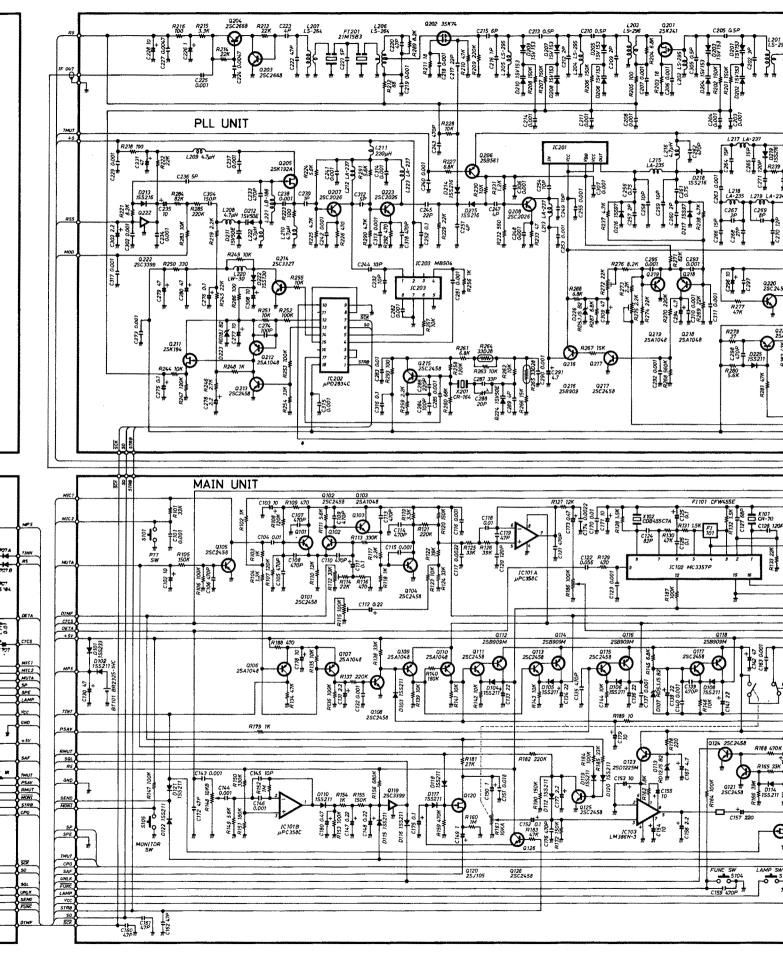








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